

# 8 W auxiliary SMPS for air-conditioner using ICE5AR4770BZS

REF\_5AR4770BZS\_8W1

## About this document

### Scope and purpose

This document is a reference design for an 8 W auxiliary SMPS for air-conditioner with the latest Infineon fifth-generation fixed-frequency CoolSET™ ICE5AR4770BZS. The power supply is designed with a universal input compatible with most geographic regions and isolated output (+12 V/1.25 A and +5 V/0.50 A) as typically employed in most home appliances.

Highlights of the auxiliary power supply for an air-conditioner:

- High efficiency under light-load conditions to meet ENERGY STAR requirements
- Simplified circuitry with good integration of power and protection features
- Auto-restart protection scheme to minimize interruption to enhance end-user experience

### Intended audience

This document is intended for power supply design or application engineers, etc. who want to design auxiliary power supplies for air-conditioners that are efficient under light-load conditions, reliable and easy to design.

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### System introduction

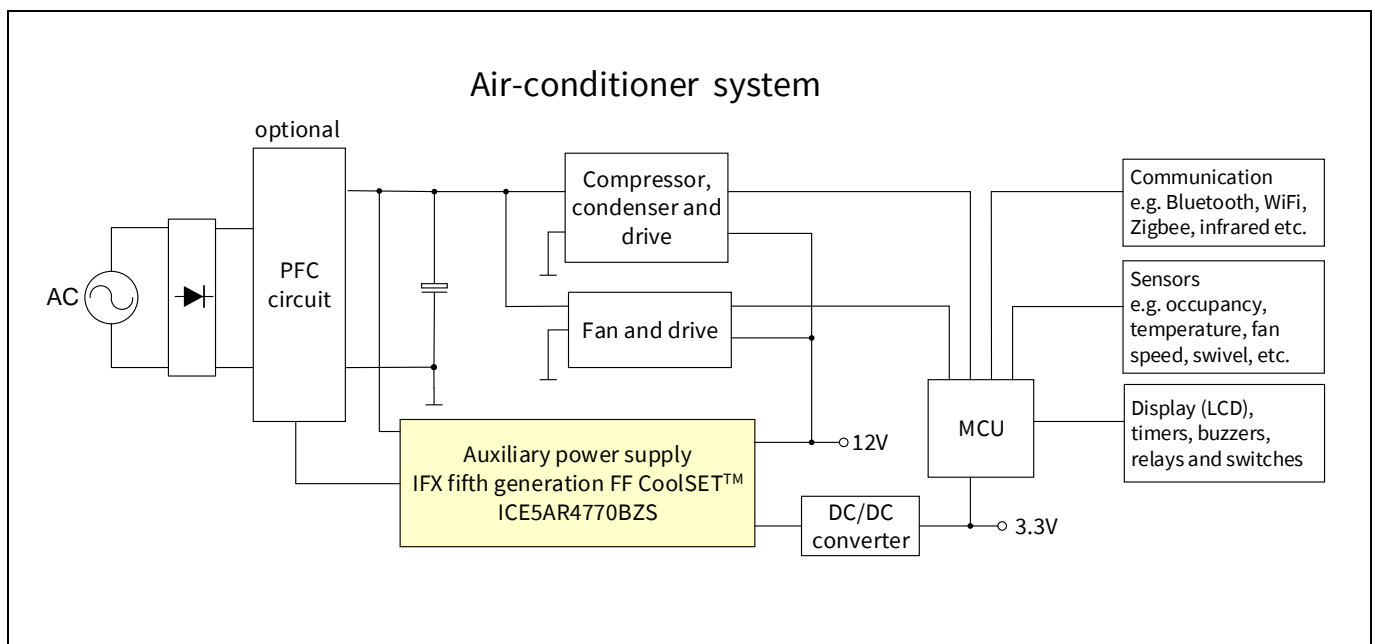
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## System introduction

## 1 System introduction

With the growing household trend for internet-connected devices, the new generation of home appliances such as air-conditioners are equipped with advanced features such as wireless control and monitoring capability, smart sensors and touch screen display. These will transform a static product into an interactive and intelligent home appliance, capable of adapting to the smart-home theme. To support this trend, Infineon has introduced the latest fifth-generation fixed-frequency CoolSET™ to address this need in an efficient and cost-effective manner.

An auxiliary SMPS is needed to power the various modules and sensors, which typically operate from a stable DC voltage source. The Infineon fifth-generation fixed-frequency CoolSET™ (as shown in Figure 1) forms the heart of the system, providing the necessary protection and AC-DC conversion from the mains to multiple regulated DC voltages to power the various blocks.



**Figure 1** Simplified air-conditioner system block diagram

Table 1 lists the system requirements for an air-conditioner, and the corresponding Infineon solution is shown in the right-hand column.

**Table 1** System requirements and Infineon solutions

|   | System requirement for air-conditioner   | Infineon solution – ICE5AR4770BZS                       |
|---|--|---|
| 1 | High efficiency under light-load conditions to meet ENERGY STAR requirements           | New fixed-frequency control and Active Burst Mode (ABM) |
| 2 | Simplified circuitry with good integration of power and protection features            | Embedded 700 V MOSFET and controller in DIP-7 package   |
| 3 | Auto-restart protection scheme to minimize interruption to enhance end-user experience | All abnormal protections are in auto-restart mode       |

### 1.1 High efficiency under light-load conditions to meet ENERGY STAR requirements

During typical air-conditioner operation, the power requirement fluctuates according to various use cases. However, in most cases where room temperature is already stabilized, the air-conditioner will reside in an idle

### System introduction

state in which the loading toward the auxiliary power supply is low. It is crucial that the auxiliary power supply operates as efficiently as possible, because it will be in this particular state for most of the period. Under light-load conditions, losses incurred with the power switch are usually dominated by the switching operation. The choice of switching scheme and frequency plays a crucial role in ensuring high conversion efficiency.

In this reference design, ICE5AR4770BZS was primarily chosen due to its frequency reduction switching scheme. Compared with a traditional fixed-frequency flyback, the CoolSET™ reduces its switching frequency from medium to light load, thereby minimizing switching losses. Therefore, an efficiency of more than 80 percent is achievable under 25 percent loading conditions.

### 1.2 Simplified circuitry with good integration of power and protection features

To relieve the designer of the complexity of PCB layout and circuit design, CoolSET™ is a highly integrated device with both a controller and HV MOSFET integrated in a single, space-saving DIP-7 package. These certainly help the designer to reduce component count as well as simplifying the layout into a single-layer PCB design for ease of manufacturing, using the traditional cost-effective wave-soldering process.

### 1.3 Auto-restart protection scheme to minimize interruption and enhance end-user experience

For an air-conditioner, it would be annoying to both the end user and the manufacturer if the system were to halt and latch after protection. To minimize interruption, the CoolSET™ implements auto-restart mode for all abnormal protections.

## 2 Reference design board

This document provides complete design details including specifications, schematics, Bill of Materials (BOM), PCB layout, and transformer design and construction information. Performance results pertaining to line/load regulation, efficiency, transient load, thermal conditions, conducted EMI scans and so on are also included.

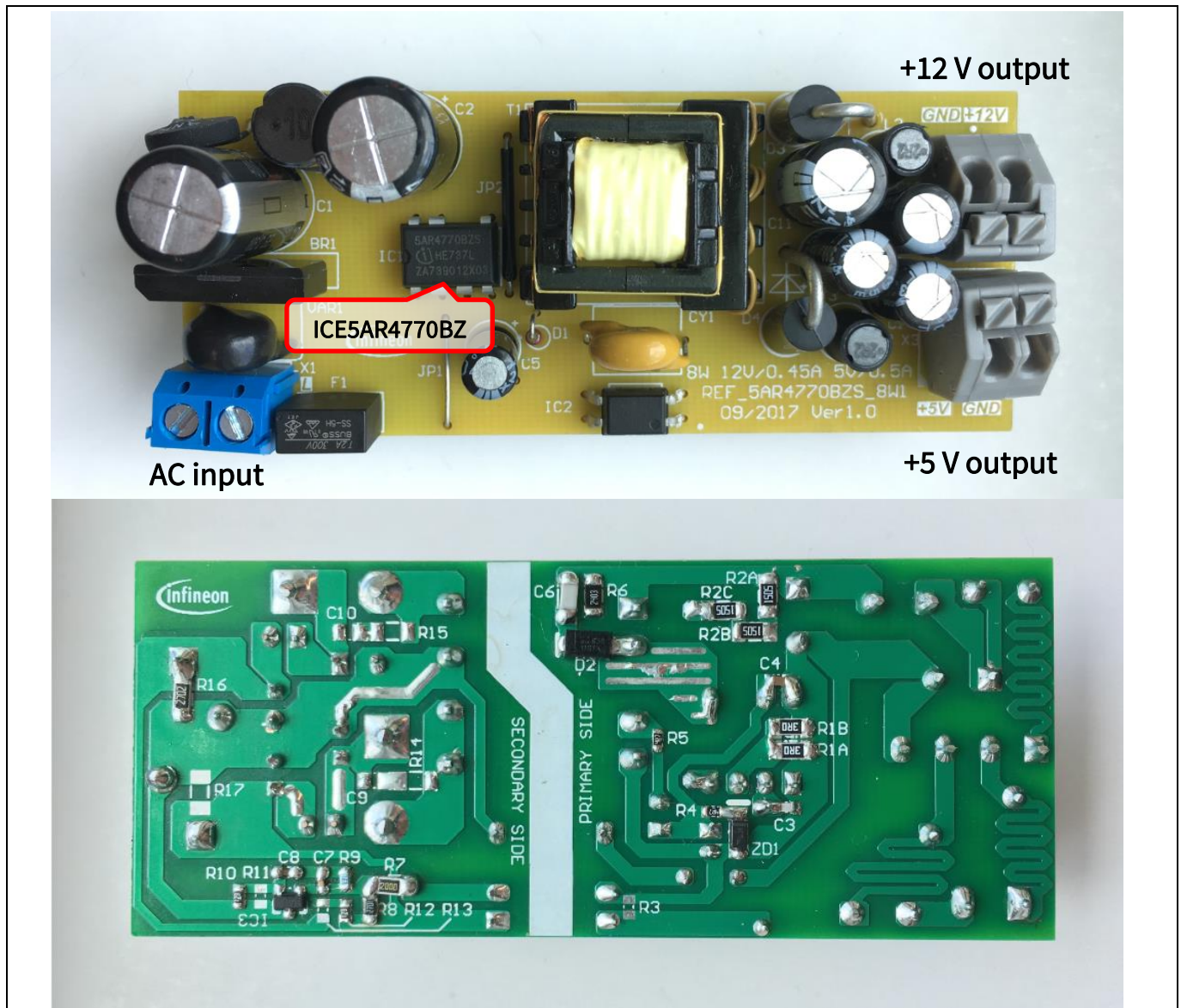


Figure 2      REF\_5AR4770BZS\_8W1

## Power supply specifications

### 3 Power supply specifications

The table below represents the minimum acceptance performance of the design. Actual performance is listed in the measurements section.

**Table 2** Specifications of REF\_5AR4770BZS\_8W1

| Description  | Symbol               | Min.         | Typ.  | Max. | Units           | Comments   |
|--|----------------------|--------------|-------|------|-----------------|--|
| <b>Input</b>   |                      |              |       |      |                 |  |
| Voltage  | V <sub>IN</sub>      | 85           | –     | 265  | V AC            | Two wires (no P.E.)                                      |
| Frequency  | f <sub>LINE</sub>    | 47           | 50/60 | 64   | Hz              |  |
| No-load input power  | P <sub>stby_NL</sub> | –            | –     | 40   | mW              |  |
| <b>Output</b>  |                      |              |       |      |                 |  |
| Output voltage 1   | V <sub>OUT1</sub>    | –            | 12    | –    | V               | ± 15 percent   |
| Output current 1   | I <sub>OUT1</sub>    | 60           | –     | 450  | mA              | 20 MHz BW<br>± 1 percent                                 |
| Output voltage ripple 1  | V <sub>RIPPLE1</sub> | –            | –     | 100  | mV              |  |
| Output voltage 2   | V <sub>OUT2</sub>    | –            | 5     | –    | V               |  |
| Output current 2   | I <sub>OUT2</sub>    | 10           | –     | 500  | mA              | 20 MHz BW  |
| Output voltage ripple 2  | V <sub>RIPPLE2</sub> | –            | –     | 100  | mV              |  |
| Max. power output  | P <sub>OUT_Max</sub> | –            | –     | 7.9  | W               |  |
| <b>Efficiency</b>  |                      |              |       |      |                 |  |
| Max. load  | η                    | –            | 83    | –    | Percent         | 115 V AC/230 V AC  |
| Average efficiency at 25 percent, 50 percent, 75 percent and 100 percent of P <sub>OUT_Max</sub> | η <sub>avg</sub>     | 82           | –     | –    | Percent         | 115 V AC/230 V AC  |
| <b>Environmental</b>   |                      |              |       |      |                 |  |
| Conducted EMI  |                      | 6            | –     | –    | dB              | Margin, CISPR 22 class B<br>EN 61000-4-2<br>EN 61000-4-5 |
| ESD  |                      | 10           | –     | –    | kV              |  |
| Surge immunity   |                      |              |       |      |                 |  |
| Differential mode  |                      | 2            | –     | –    | kV              |  |
| Common mode  |                      | 4            | –     | –    | kV              |  |
| Ambient temperature  | T <sub>amb</sub>     | 0            | –     | 50   | °C              | Free convection, sea level                               |
| Form factor  |                      | 85 × 35 × 25 |       |      | mm <sup>3</sup> | L × W × H  |

## 4 Circuit diagram

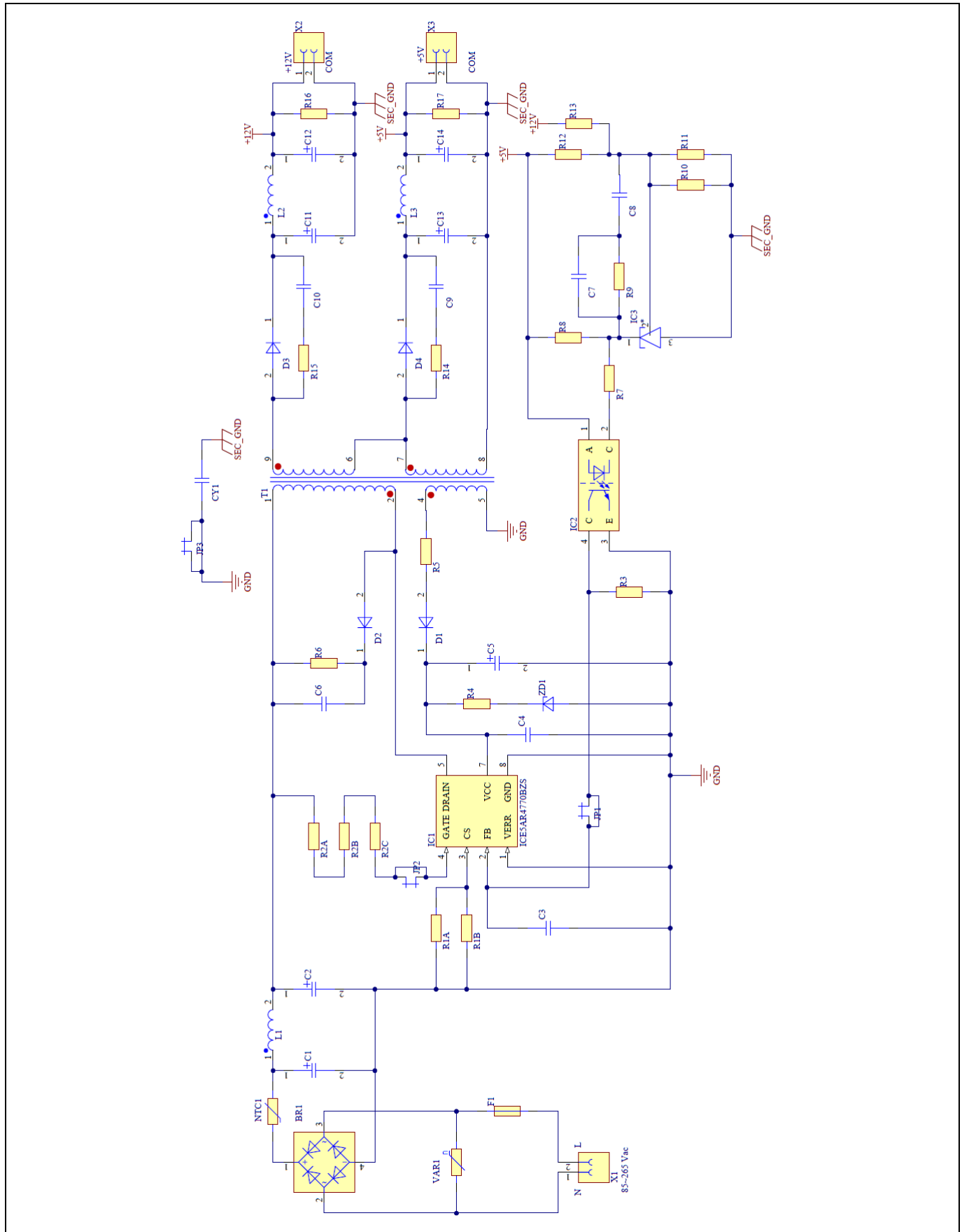


Figure 3 Schematic of REF\_5AR4770BZS\_8W1



### Circuit description

## 5 Circuit description

In this section, the design circuit for the SMPS unit will be briefly described by the different functional blocks. For details of the design procedure and component selection for the flyback circuitry please refer to the IC design guide [2] and calculation tool [3].

### 5.1 EMI filtering and line rectification

The input of power supply unit is taken from the AC power grid, which is in the range of 85 V AC ~ 265 V AC. The fuse F1 is directly connected to the input line to protect the system in case of excess current entering the system circuit due to any fault. Following is the varistor VAR1, which is connected across the input to absorb excessive energy during line surge transient. The bridge rectifier BR1 rectifies the AC input into DC voltage, filtered by the bulk capacitors C1 and C2. Resistor NTC1 not only reduces the inrush current during start-up but it also helps reduce the voltage increase on the bulk capacitors C1 and C2 during line surge transients. Inductor L1 and capacitors C1 and C2 form a  $\pi$  filter to attenuate EMI noise.

### 5.2 Flyback converter power stage

The flyback converter power stage consists of transformer T1, a primary HV MOSFET (integrated into ICE5AR4770BZS), secondary rectification diodes D3 and D4, secondary output capacitors C11, C12, C13 and C14 and output filter inductors L2 and L3.

When the primary HV MOSFET turns on, energy is stored in the transformer. When it turns off, the stored energy is discharged to the output capacitors and into the output load.

Primary winding has two layers placed back to back for higher winding capacitance. This can reduce EMI by slowing the MOSFET switching. However, this can reduce efficiency. Winding capacitance can be tuned by adding a number of isolation tapes between the layers, depending on the EMI or efficiency need. If efficiency is a priority, interlacing primary and secondary winding is recommended, as it has lower leakage inductance. As a result, the clamper circuit can be relaxed to reduce its power losses.

For the output rectification, lower forward voltage and ultra-fast recovery diodes can improve efficiency. Capacitors C11 and C13 store the energy needed during output load jumps. LC filters L2/C12 and L3/C14 reduce the HF ripple voltage.

### 5.3 Control of flyback converter through fifth-generation fixed-frequency CoolSET™ ICE5AR4770BZS

#### 5.3.1 Integrated HV power MOSFET

The ICE5AR4770BZS CoolSET™ is a seven-pin device in a DIP-7 package. It has been integrated with the new fixed-frequency PWM controller and all necessary features and protections, and most importantly the 700 V power MOSFET, Infineon Superjunction (SJ) CoolMOS™. Hence, the schematic is much simplified and the circuit design is made much easier.

#### 5.3.2 Current Sensing (CS)

The ICE5AR4770BZS is a current mode controller. The primary peak current is controlled cycle-by-cycle through the CS resistors R1A and R1B in the CS pin (pin 3). Transformer saturation can be avoided through Peak Current Limitation (PCL); therefore, the system is more protected and reliable.



## Circuit description

### 5.3.3 Feedback (FB) and compensation network

$V_{OUT}$  is sensed by resistor dividers R10, R11, R12 and R13 connected to the input of error amplifier TL431 (IC3). A type 2 compensation network (C7, C8 and R9) is connected to the input and output of IC3. The output of IC3 is coupled to the FB pin via optocoupler IC2.

The FB pin of ICE5AR4770BZS is a multi-function pin, which is used to select the entry/exit burst power level through the resistor at the FB pin (R3) and also the burst-on/burst-off sense input during ABM.

## 5.4 Unique features of the fifth generation fixed-frequency CoolSET™ ICE5AR4770BZS

### 5.4.1 Fast self-start-up and sustaining of $V_{CC}$

The IC uses a cascode structure to fast charge the  $V_{CC}$  capacitor. Pull-up resistors R2A, R2B and R2C connected to the GATE pin (pin 4) is used to initiate the start-up phase. At first, 0.2 mA is used to charge the  $V_{CC}$  capacitor from 0 V to 1.1 V. This is a protection which reduces the power dissipation of the IC during  $V_{CC}$  short-to-GND condition. Thereafter, a much higher charging current of 3.2 mA will charge the  $V_{CC}$  capacitor until the  $V_{CC\_ON}$  is reached. Start-up time of less than 200 ms is achievable with  $V_{CC}$  capacitor of 22  $\mu$ F.

After start-up, the IC  $V_{CC}$  supply is sustained by the auxiliary winding of transformer TR1, which needs to support the  $V_{CC}$  to be above Under Voltage Lockout (UVLO) voltage (10 V typ.) through the rectifier circuit D12, R12, R12A and C16.

### 5.4.2 CCM, DCM operation with frequency reduction

ICE5AR4770BZS can be operated in either Discontinuous Conduction Mode (DCM) or Continuous Conduction Mode (CCM) with frequency-reduction feature. This reference board is designed to operate in DCM. When the system is operating at high output load, the controller will switch at 100 kHz fixed frequency. In order to achieve a better efficiency between light load and medium load, frequency reduction is implemented as a function of  $V_{FB}$ , as shown in Figure 4. Switching frequency will not reduce further once the minimum switching frequency  $f_{OSC2\_MIN}$  (43 kHz) is reached.

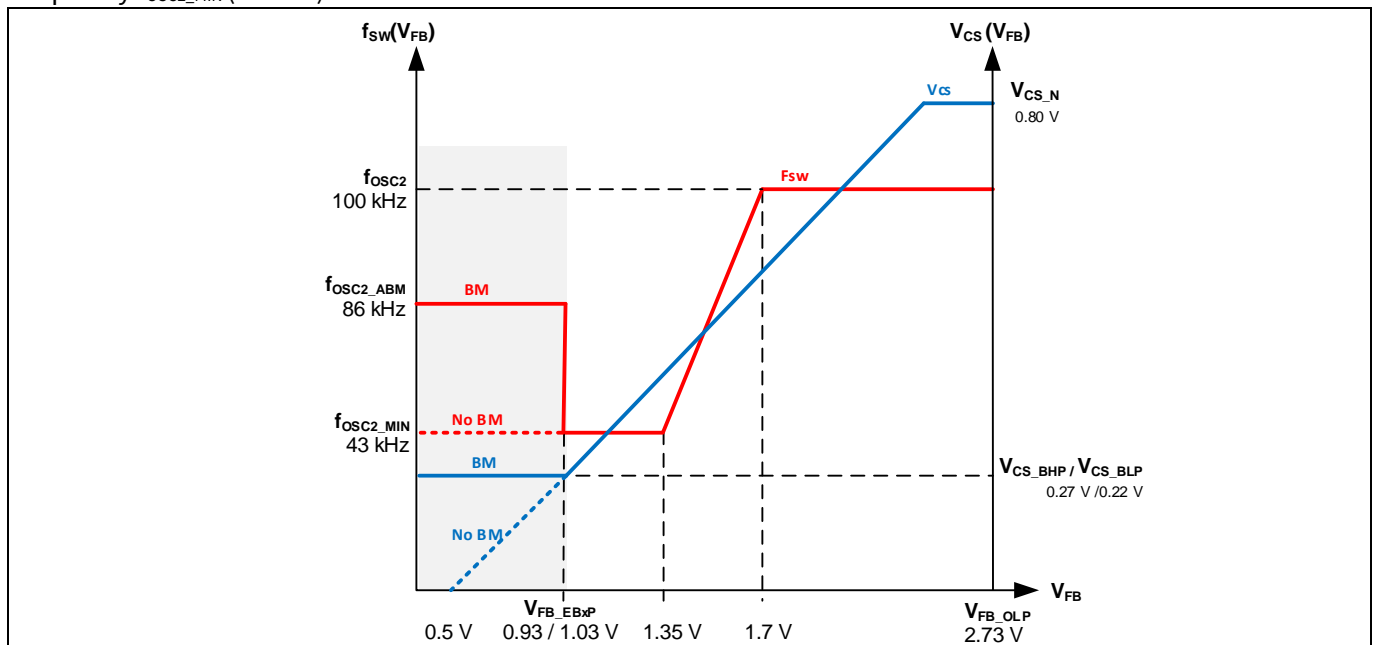


Figure 4 Frequency-reduction curve

## Circuit description

### 5.4.3 Frequency jittering with modulated gate drive

The ICE5AR4770BZS has a frequency jittering feature with modulated gate drive to reduce the EMI noise. The jitter frequency is internally set at 100 kHz ( $\pm 4$  kHz), and the jitter period is 4 ms.

### 5.4.4 System robustness and reliability through protection features

Protection is one of the major factors in determining whether the system is safe and robust – therefore sufficient protection is necessary. ICE5AR4770BZS provides comprehensive protection to ensure the system is operating safely. This includes  $V_{CC}$  OV and UV, over-load, over-temperature (controller junction), CS short-to-GND and  $V_{CC}$  short-to-GND. When those faults are found, the system will enter into protection mode. Once the fault is removed, the system resumes normal operation. A list of protections and the failure conditions is shown in the table below.

**Table 3** Protection functions of ICE5AR4770BZS

| Protection function  | Failure condition  | Protection mode         |
|--|--|-------------------------|
| $V_{CC}$ OV  | $V_{VCC}$ greater than 25.5 V  | Odd-skip auto restart   |
| $V_{CC}$ UV  | $V_{VCC}$ less than 10 V   | Auto restart            |
| Over-load  | $V_{FB}$ greater than 2.75 V and lasts for 54 ms                             | Odd-skip auto restart   |
| Over-temperature (junction temperature of controller chip only)                              | $T_J$ greater than 140°C   | Non-switch auto restart |
| CS short-to-GND  | $V_{CS}$ less than 0.1 V, lasts for 0.4 $\mu$ s and three consecutive pulses | Odd-skip auto restart   |
| $V_{CC}$ short-to-GND<br>( $V_{VCC} = 0$ V, start-up = 50 M $\Omega$ and $V_{DRAIN} = 90$ V) | $V_{VCC}$ less than 1.1 V, $I_{VCC\_Charge1} \approx -0.2$ mA                | Cannot start up         |

### 5.5 Clamper circuit

A clamper network consisting of D2, C6 and R6 is used to reduce the switching voltage spikes on the DRAIN pin, which are generated by the leakage inductance of the transformer TR1. This is a dissipative circuit, therefore R6 and C6 need to be fine-tuned depending on the voltage derating factor and efficiency requirement.

### 5.6 PCB design tips

For a good PCB design layout, there are several points to note.

- The switching power loop needs to be as small as possible (see Figure 5). There are three power loops in the reference design; one on the primary side and two on the secondary side. The primary-side loop starts from the bulk capacitor (C2) positive terminal, goes through the primary transformer winding (pin 1 and pin 2 of T1), the DRAIN pin and CS pin of the CoolSET™ IC1, CS resistors R1A and R1B and back to the C2 negative terminal. The secondary-side loop starts at the 12 V output secondary transformer winding (pin 9 of T1), goes through output diode D3, output capacitor C11 and back to pin 8 of T1. Another loop on the secondary starts from the 5 V output secondary transformer winding (pin 6 and 7 of T1), output diode D4, output capacitor C13 and back to pin 8 of T1.
- Star-ground connection should be used to reduce HF noise coupling that can affect the functional operation. The ground of the small-signal components, e.g. C3 and C4, and the emitter of the optocoupler (pin 3 of IC2) should connect directly to the IC ground (pin 8 of IC1).

## Circuit description

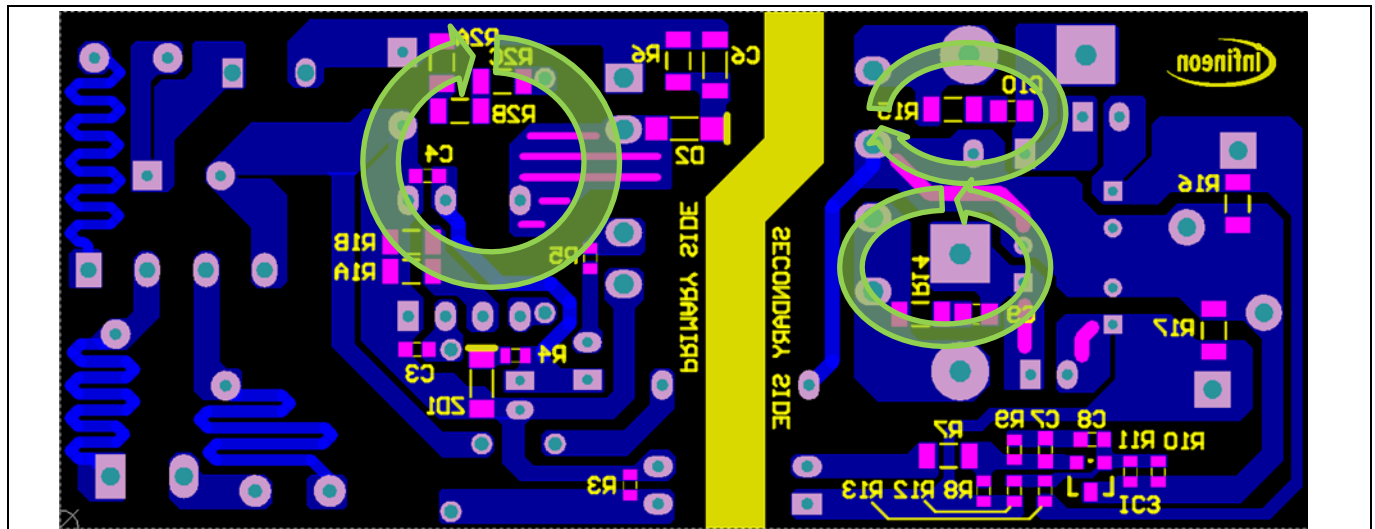


Figure 5 PCB layout tips

- Adding thin PCB track (zigzag trace) on the AC input side can increase input series resistance, which may eliminate the use of NTC1 to pass lower line surge requirements.
- Separating the HV components and LV components, e.g. clamper circuit D12, R6 and C6, at the top part of the PCB (see Figure 5) and the other LV components at the lower part of the PCB can reduce the spark-over chance of the high energy surge during ESD or a lightning surge test.
- Make the PCB copper pour area on the DRAIN pin as wide as possible to act as a heatsink for the CoolSET™.

## 5.7 EMI reduction tips

EMI compliance is always a challenge for the power supply designer. There are several critical points to consider in order to achieve a satisfactory EMI performance.

- A proper transformer design can significantly reduce EMI. Low leakage inductance can incur a low switching spike and HF noise. Interlaced winding technique is the most common practice to reduce leakage inductance. Winding shield, core shield and whole transformer shield are also some of the techniques used to reduce EMI.
- An input CMC and X-capacitor greatly reduce EMI but are costly and impractical, especially for low-power applications.
- Short-switching power-loop design in the PCB (as described in section 5.6) can reduce radiated EMI due to the antenna effect.
- The Y-capacitor CY1 dampens the HF noise generated between the primary and secondary, reducing the EMI noise.
- A secondary diode snubber circuit (R14/C9 and R15/C10) can reduce HF noise.
- Ferrite beads can reduce HF noise especially on critical nodes such as the DRAIN pin, clamper diode and secondary diode terminals.
- The addition of output CMC is also effective where long cable wires are used to connect the output of the power supply to the load.

## 6 PCB layout

## 6.1 Top side

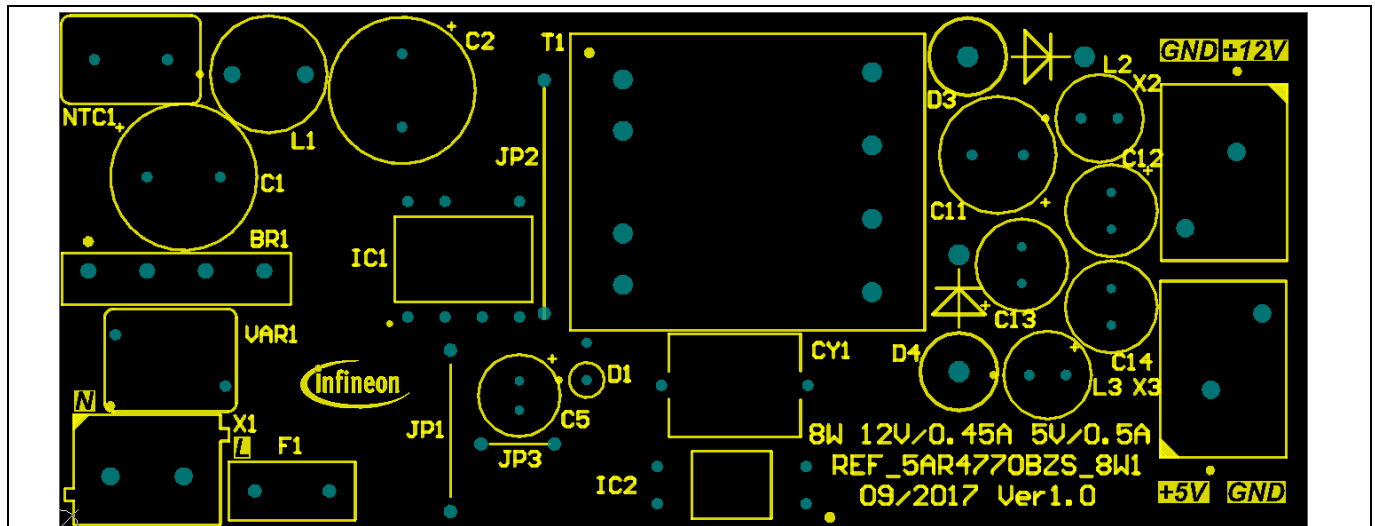
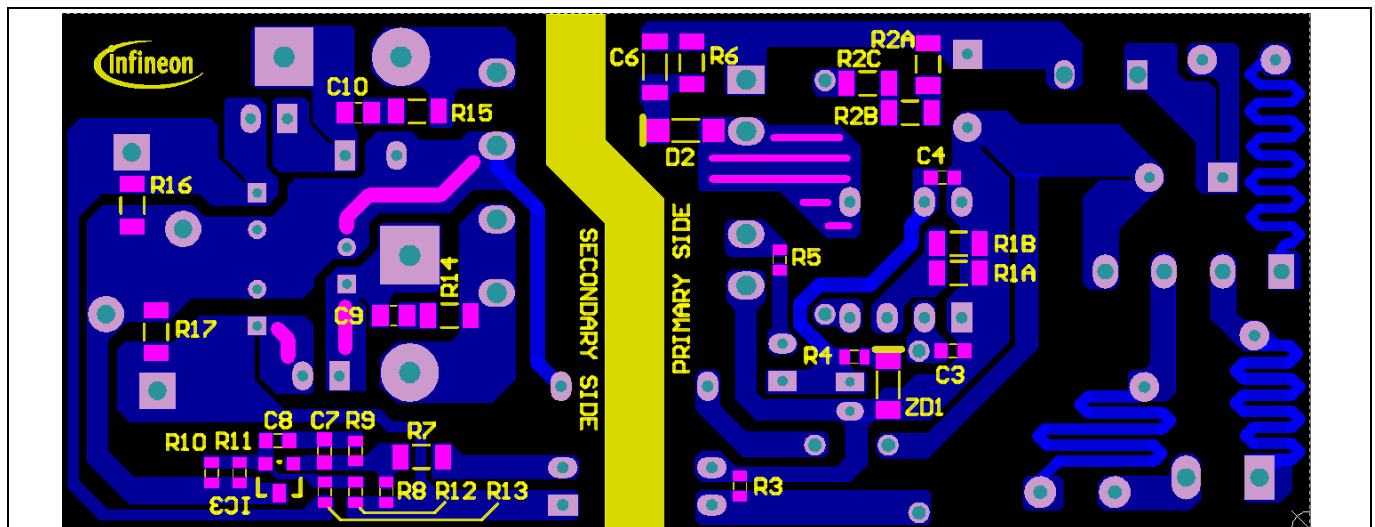


Figure 6 Top-side component legend

## 6.2 Bottom side



**Figure 7**      **Bottom-side copper and component legend**

## BOM

## 7 BOM

Table 4 BOM

| No. | Designator                  | Description   | Part number        | Manufacturer      | Quantity |
|-----|-----------------------------|---|--------------------|-------------------|----------|
| 1   | BR1                         | 600 V/1 A   | S1VBA60            |                   | 1        |
| 2   | C1, C2                      | 10 $\mu$ F/400 V  | EEUEE2G100         | Panasonic         | 2        |
| 3   | C3                          | 10 nF/50 V/0603   |                    |                   | 1        |
| 4   | C4                          | 100 nF/50 V/0603  |                    |                   | 1        |
| 5   | C5                          | 22 $\mu$ F/50 V   | 50YXJ22MTA5X11     | Rubycon           | 1        |
| 6   | C6                          | 470 pF/630 V/1206   |                    |                   | 1        |
| 7   | C7                          | 1 nF/50 V/0603  |                    |                   | 1        |
| 8   | C8                          | 220 nF/50 V/0603  |                    |                   | 1        |
| 9   | C9, C10                     | Not loaded  |                    |                   |          |
| 10  | C11                         | 470 $\mu$ F/16 V  | 16ZLH470MEFC8X11.5 | Rubycon           | 1        |
| 11  | C12                         | 220 $\mu$ F/16 V  | 16ZLH220MEFC6.3X11 | Rubycon           | 1        |
| 12  | C13, C14                    | 330 $\mu$ F/10 V  | 10ZLJ330M6.3X11    | Rubycon           | 2        |
| 13  | CY1                         | 1 nF/500 V  | VY1102M35YUG63V0   |                   | 1        |
| 14  | D1                          | 0.2 A/200 V   | BAV20              |                   | 1        |
| 15  | D2                          | 1 A/1 kV  | US1K-13-F          |                   | 1        |
| 16  | D3                          | 3 A/150 V   | STPS3150RL         |                   | 1        |
| 17  | D4                          | 3 A/60 V  | MBR360G            |                   | 1        |
| 18  | F1                          | 2 A/300 V   | SS-5H-2A-APH       | Eaton Bussmann    | 1        |
| 19  | IC1                         | 700 V/4.7 $\Omega$  | ICE5AR4770BZS      | Infineon          | 1        |
| 20  | IC2                         | Optocoupler   | SFH617A-3          |                   | 1        |
| 21  | IC3                         | 2.5 V ref.  | TL431AQDBZRQ1      |                   | 1        |
| 22  | L1                          | 1 mH/0.3 A  | 744 772 102        | Würth Electronics | 1        |
| 23  | L2, L3                      | 2.2 $\mu$ H/4.3 A   | 744 746 202 2      | Würth Electronics | 2        |
| 24  | NTC1                        | 5 $\Omega$ /9.5 mm  | B57235S0509M000    | TDK               | 1        |
| 25  | R1A, R1B                    | 3 $\Omega$ /0.25 W/1 percent/1206                             | ERJ8RQF3R0V        | Panasonic         | 2        |
| 26  | R2A, R2B, R2C               | 15 M $\Omega$ /0.33 W/1 percent/1206                          |                    |                   | 3        |
| 27  | R4, R5                      | 4.7 $\Omega$ /0.1 W/5 percent/0603                            |                    |                   | 2        |
| 28  | R6                          | 240 k $\Omega$ /0.25 W/5 percent/1206                         | ERA8AEB244V        | Panasonic         | 1        |
| 29  | R7                          | 330 $\Omega$ /0.25 W/5 percent/1206                           |                    |                   | 1        |
| 30  | R8                          | 2.7 k $\Omega$ /0.1 W/5 percent/0603                          |                    |                   | 1        |
| 31  | R9                          | 18 k $\Omega$ /0.1 W/1 percent/0603                           |                    |                   | 1        |
| 32  | R10, R12                    | 12 k $\Omega$ /0.1 W/1 percent/0603                           |                    |                   | 2        |
| 33  | R16                         | 27 k $\Omega$ /0.25 W/5 percent/1206                          |                    |                   | 1        |
| 34  | R3, R11, R13, R14, R15, R17 | Not loaded  |                    |                   |          |
| 35  | T1                          | 710 $\mu$ H/EE16  | 750343739          | Würth Electronics | 1        |
| 36  | VAR1                        | Varistor, 0.3 W/320 V   | ERZE07A511         | Panasonic         | 1        |
| 37  | ZD1                         | 22 V/500mW  | MMSZ5251BT1G       |                   | 1        |
| 38  | X1                          | Connector   | 691102710002       | Würth Electronics | 1        |
| 39  | X2, X3                      | Connector   | 691412120002B      | Würth Electronics | 2        |
| 40  | JP1, JP3                    | Jumper  |                    |                   | 2        |
| 41  | JP2                         | Insulated jumper  |                    |                   | 1        |
| 42  | PCB                         | 85 mm $\times$ 35 mm (L $\times$ W), single layer, 2 oz, FR-4 |                    |                   | 1        |

# 8 W auxiliary SMPS for air-conditioner using ICE5AR4770BZS

REF\_5AR4770BZS\_8W1

## Transformer specification

### 8 Transformer specification

(Refer to Appendix A for transformer design and Appendix B for WE transformer specification.)

Würth Electronics core part number: 150-2182 (EE16/8/5)

Würth Electronics bobbin: 070-5280 (9-pin EXT, THT, horizontal version)

Primary inductance:  $L_p = 710 \mu\text{H}$  ( $\pm 10$  percent), measured between pin 1 and pin 2

Manufacturer and part number: Würth Electronics Midcom (750343739)

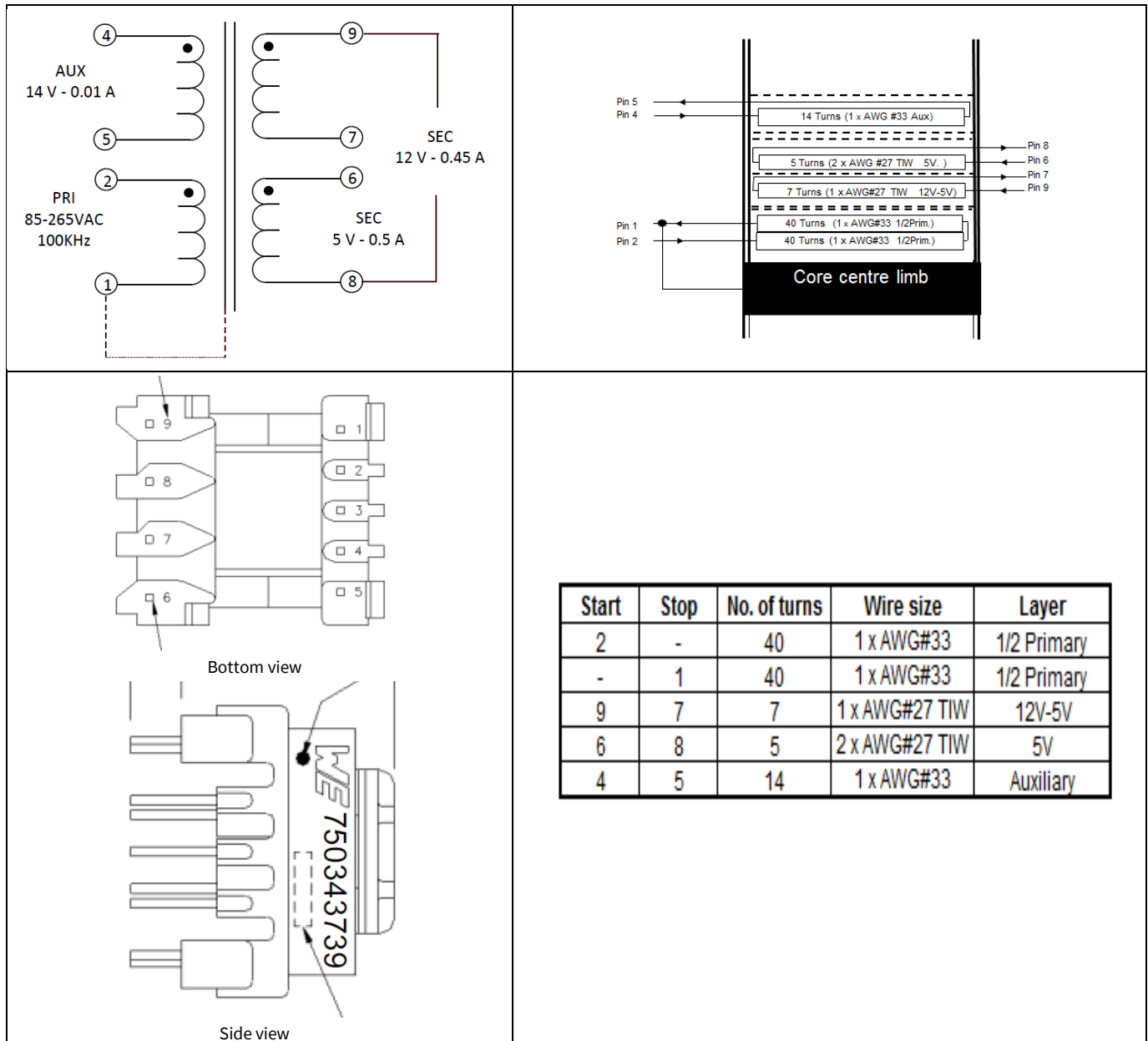


Figure 8 Transformer structure

## 9 Measurement data and graphs

Table 5 Electrical measurements

| Input<br>(V AC/Hz) | Pin<br>(W) | 12 V<br>(V) | I <sub>out_12V</sub><br>(mA) | 5 V<br>(V) | I <sub>out_5V</sub><br>(mA) | 12 V <sub>RPP</sub><br>(mV) | 5 V <sub>RPP</sub><br>(mV) | P <sub>OUT</sub><br>(W) | Efficiency<br>(percent) | Average<br>efficiency<br>(percent) | OLP<br>pin<br>(W) | OLP I <sub>out_12V</sub><br>(fixed 5 V at<br>0.5 A) (A) |
|--------------------|------------|-------------|------------------------------|------------|-----------------------------|-----------------------------|----------------------------|-------------------------|-------------------------|------------------------------------|-------------------|---|
| 85 V AC/<br>60 Hz  | 0.023      | 12.56       | 0                            | 4.99       | 0                           | 17                          | 23                         |                         |                         |                                    | 13.73             | 0.694   |
|                    | 1.022      | 12.40       | 44.8                         | 4.99       | 50                          | 15                          | 13                         | 0.81                    | 78.81                   |                                    |                   |   |
|                    | 2.470      | 12.43       | 112.3                        | 4.99       | 125.1                       | 17                          | 17                         | 2.02                    | 81.79                   | 82.20                              |                   |   |
|                    | 4.898      | 12.45       | 224.8                        | 4.99       | 250.1                       | 18                          | 18                         | 4.05                    | 82.61                   |                                    |                   |   |
|                    | 7.367      | 12.46       | 337.2                        | 4.99       | 375.2                       | 22                          | 18                         | 6.07                    | 82.46                   |                                    |                   |   |
|                    | 9.902      | 12.49       | 449.6                        | 4.99       | 500.1                       | 25                          | 22                         | 8.11                    | 81.93                   |                                    |                   |   |
| 115 V AC/<br>60 Hz | 0.024      | 12.56       | 0                            | 4.99       | 0                           | 18                          | 25                         |                         |                         |                                    | 13.57             | 0.706   |
|                    | 1.025      | 12.40       | 44.8                         | 4.99       | 50                          | 15                          | 15                         | 0.81                    | 78.54                   |                                    |                   |   |
|                    | 2.463      | 12.43       | 112.3                        | 4.99       | 125.1                       | 17                          | 17                         | 2.02                    | 82.05                   | 82.90                              |                   |   |
|                    | 4.864      | 12.45       | 224.8                        | 4.99       | 250.1                       | 18                          | 17                         | 4.05                    | 83.19                   |                                    |                   |   |
|                    | 7.298      | 12.46       | 337.2                        | 4.99       | 375.2                       | 20                          | 18                         | 6.07                    | 83.23                   |                                    |                   |   |
|                    | 9.757      | 12.49       | 449.6                        | 4.99       | 500.1                       | 23                          | 20                         | 8.11                    | 83.13                   |                                    |                   |   |
| 230 V AC/<br>50 Hz | 0.027      | 12.58       | 0                            | 4.99       | 0                           | 18                          | 27                         |                         |                         |                                    | 13.78             | 0.734   |
|                    | 1.038      | 12.41       | 44.8                         | 4.99       | 50                          | 15                          | 15                         | 0.81                    | 77.61                   |                                    |                   |   |
|                    | 2.524      | 12.43       | 112.3                        | 4.99       | 125.1                       | 17                          | 18                         | 2.02                    | 80.06                   | 82.10                              |                   |   |
|                    | 4.941      | 12.44       | 224.8                        | 4.99       | 250.1                       | 17                          | 18                         | 4.05                    | 81.87                   |                                    |                   |   |
|                    | 7.313      | 12.45       | 337.2                        | 4.99       | 375.2                       | 22                          | 20                         | 6.07                    | 83.03                   |                                    |                   |   |
|                    | 9.715      | 12.48       | 449.6                        | 4.99       | 500.1                       | 27                          | 22                         | 8.11                    | 83.45                   |                                    |                   |   |
| 265 V AC/<br>50 Hz | 0.029      | 12.58       | 0                            | 4.99       | 0                           | 17                          | 27                         |                         |                         |                                    | 14.12             | 0.756   |
|                    | 1.076      | 12.40       | 44.8                         | 4.99       | 50                          | 15                          | 15                         | 0.81                    | 74.83                   |                                    |                   |   |
|                    | 2.550      | 12.43       | 112.3                        | 4.99       | 125.1                       | 17                          | 18                         | 2.02                    | 79.23                   | 81.40                              |                   |   |
|                    | 4.980      | 12.44       | 224.8                        | 4.99       | 250.1                       | 20                          | 18                         | 4.04                    | 81.21                   |                                    |                   |   |
|                    | 7.381      | 12.45       | 337.2                        | 4.99       | 375.2                       | 23                          | 18                         | 6.07                    | 82.26                   |                                    |                   |   |
|                    | 9.779      | 12.48       | 449.6                        | 4.99       | 500.1                       | 23                          | 20                         | 8.11                    | 82.90                   |                                    |                   |   |

100 percent load condition: +5 V/500 mA and +12 V/450 mA

75 percent load condition: +5 V/375 mA and +12 V/337 mA

50 percent load condition: +5 V/250 mA and +12 V/225 mA

25 percent load condition: +5 V/125 mA and +12 V/112 mA



## Measurement data and graphs

## 9.1 Efficiency

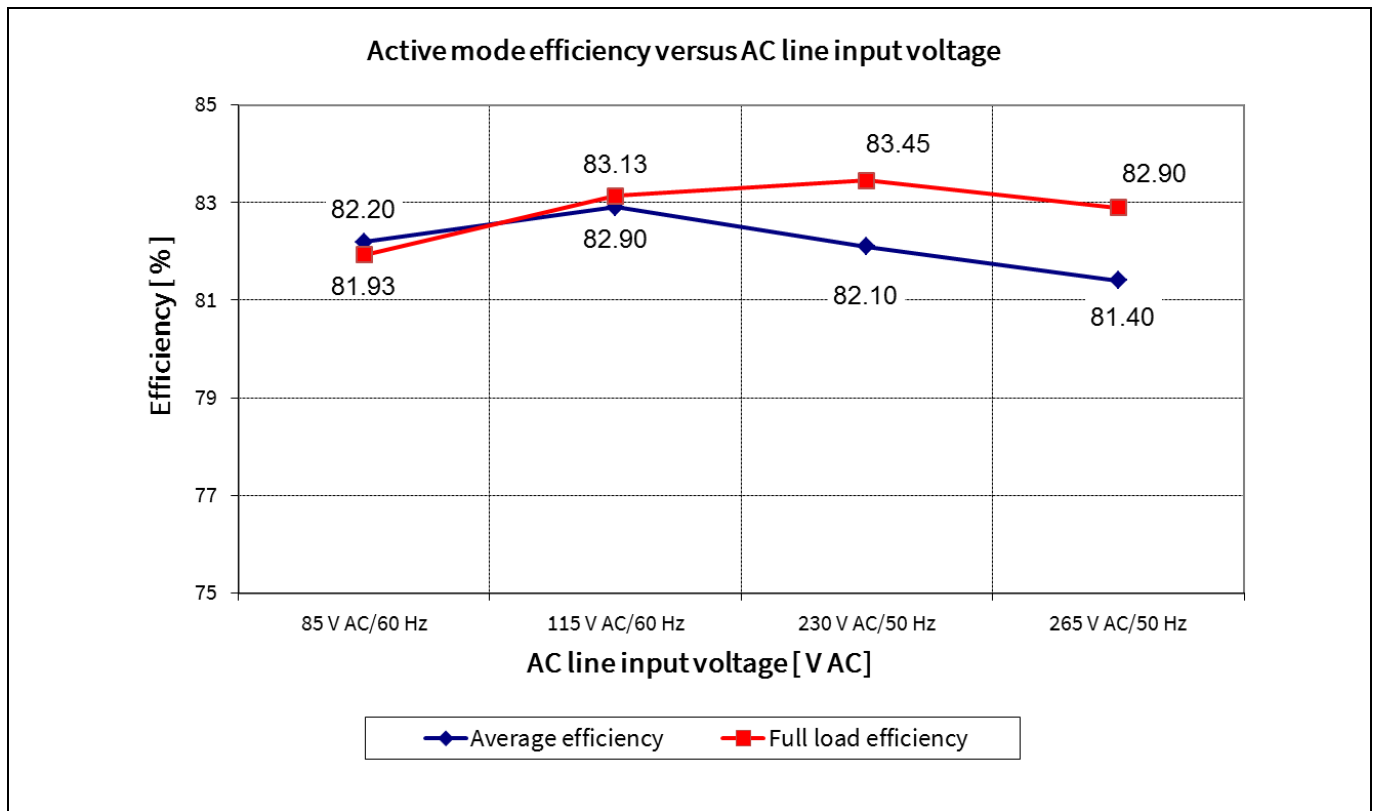


Figure 9 Efficiency vs AC-line input voltage

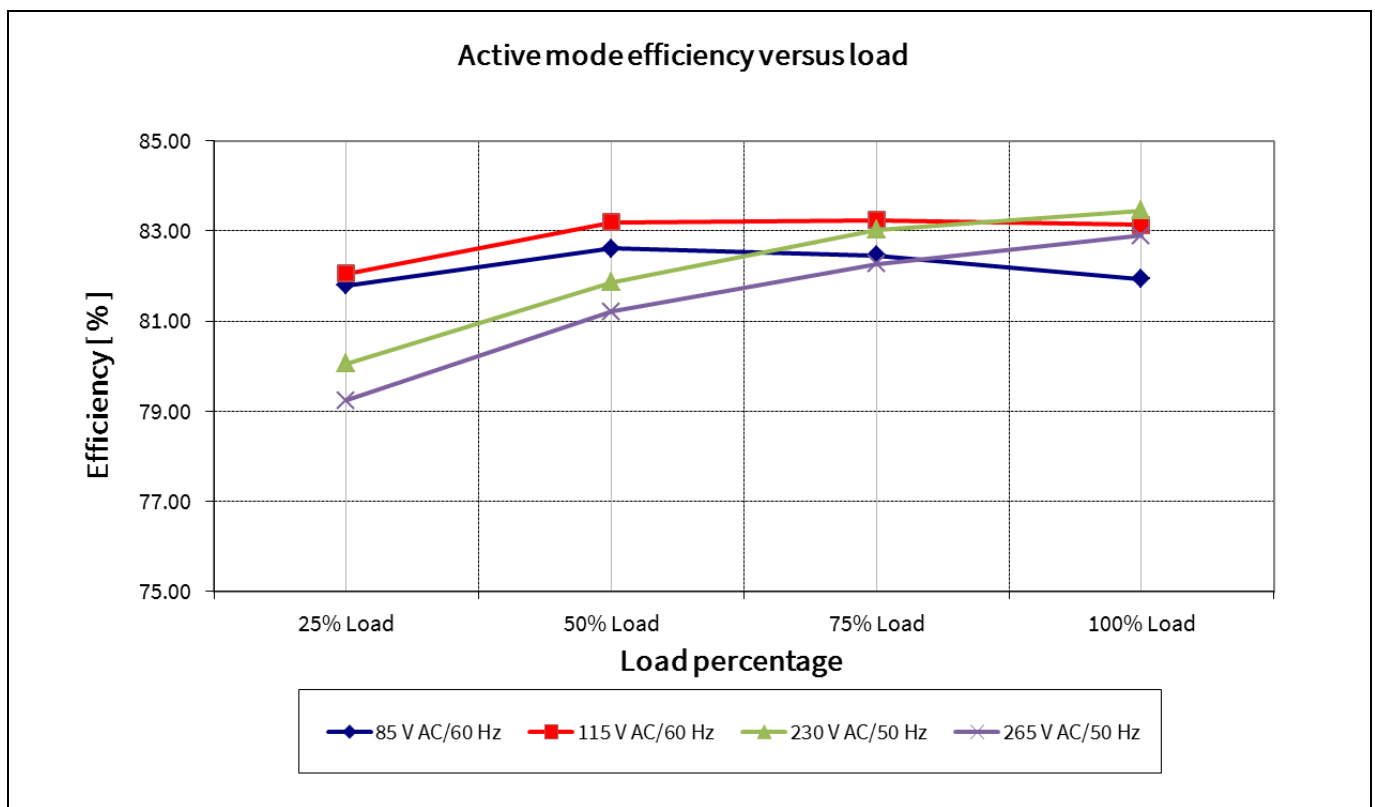


Figure 10 Efficiency vs load

## 9.2 Standby power

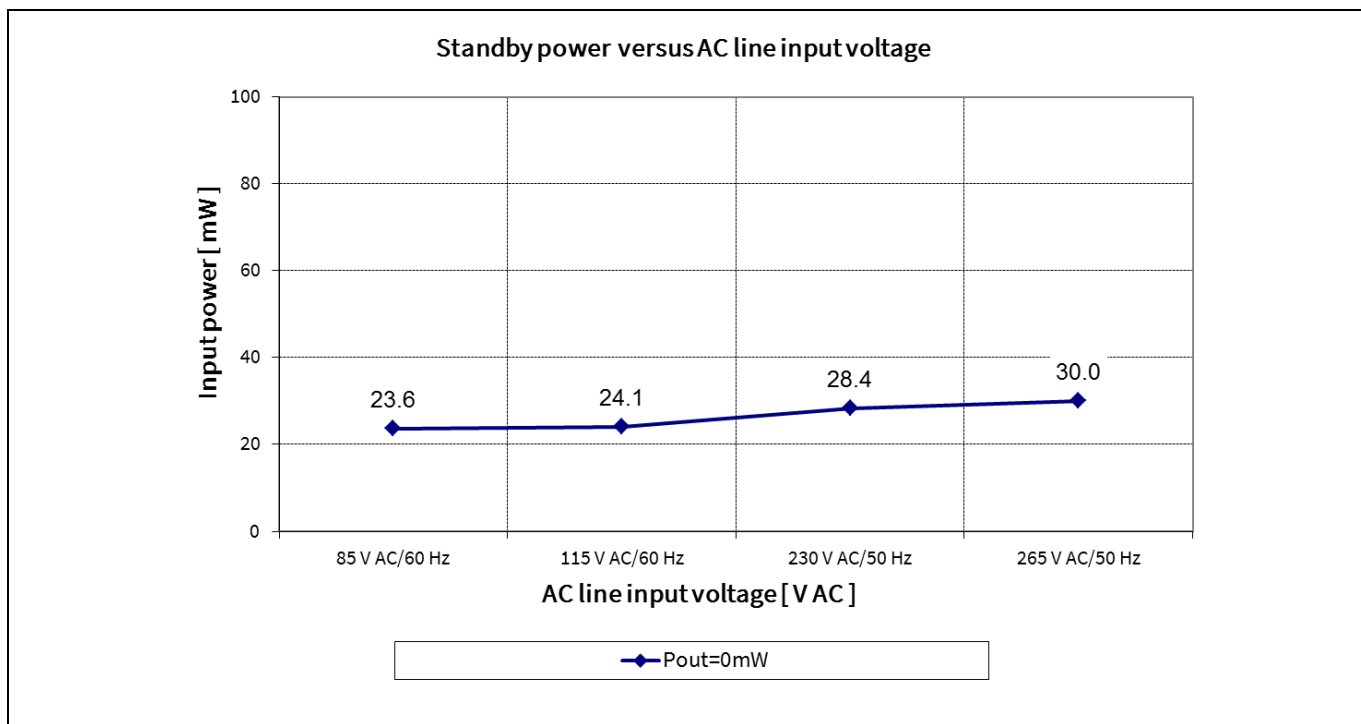


Figure 11 Standby power at no load vs AC-line input voltage (measured by Yokogawa WT210 power meter – integration mode)

## 9.3 Line regulation

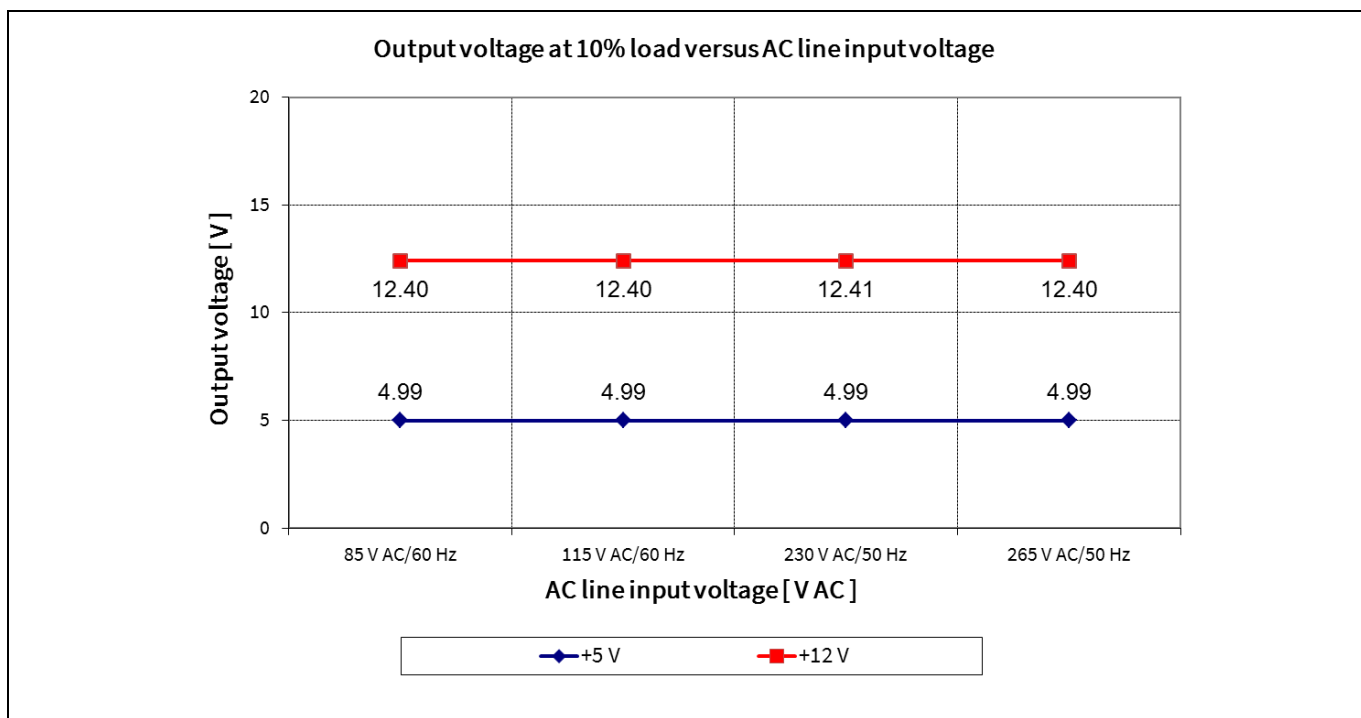


Figure 12 Output regulation at full load vs AC-line input voltage

## 9.4 Load regulation

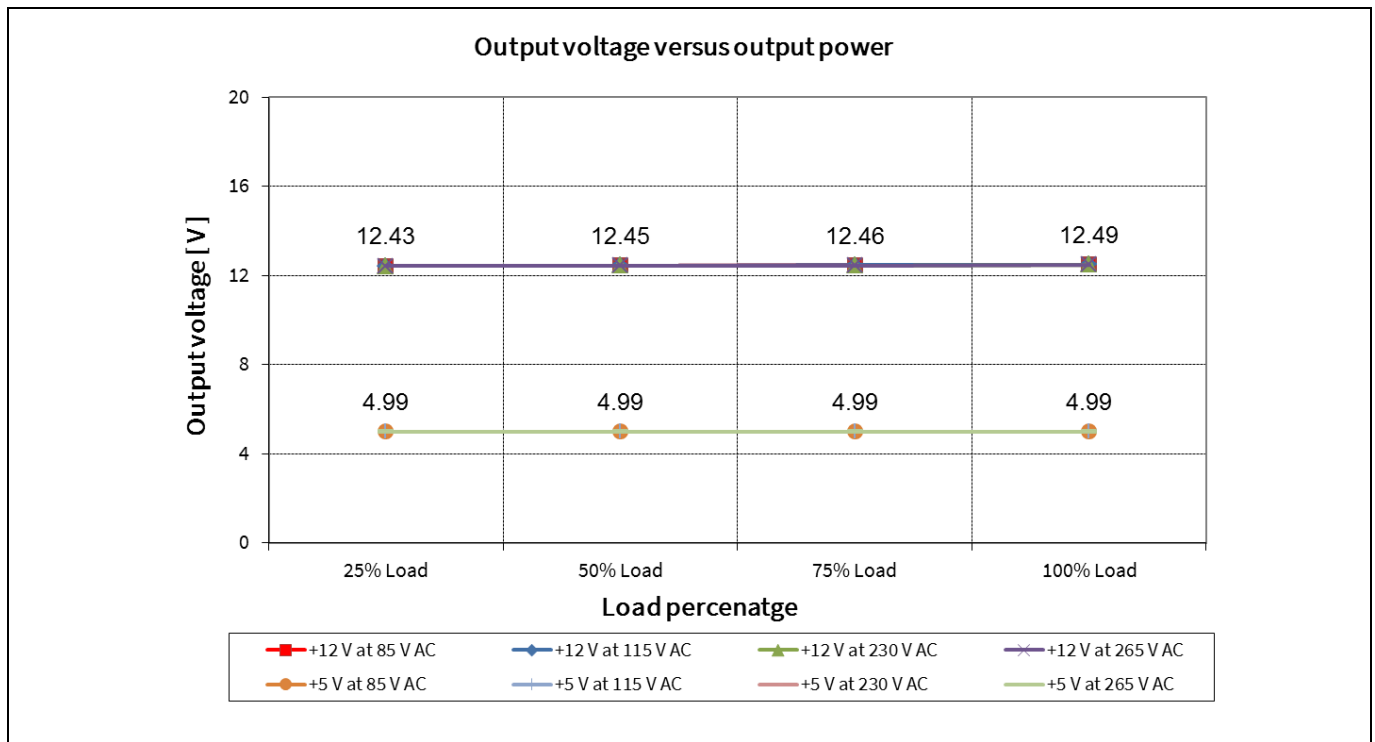


Figure 13 Output regulation vs output power

## 9.5 Maximum input power

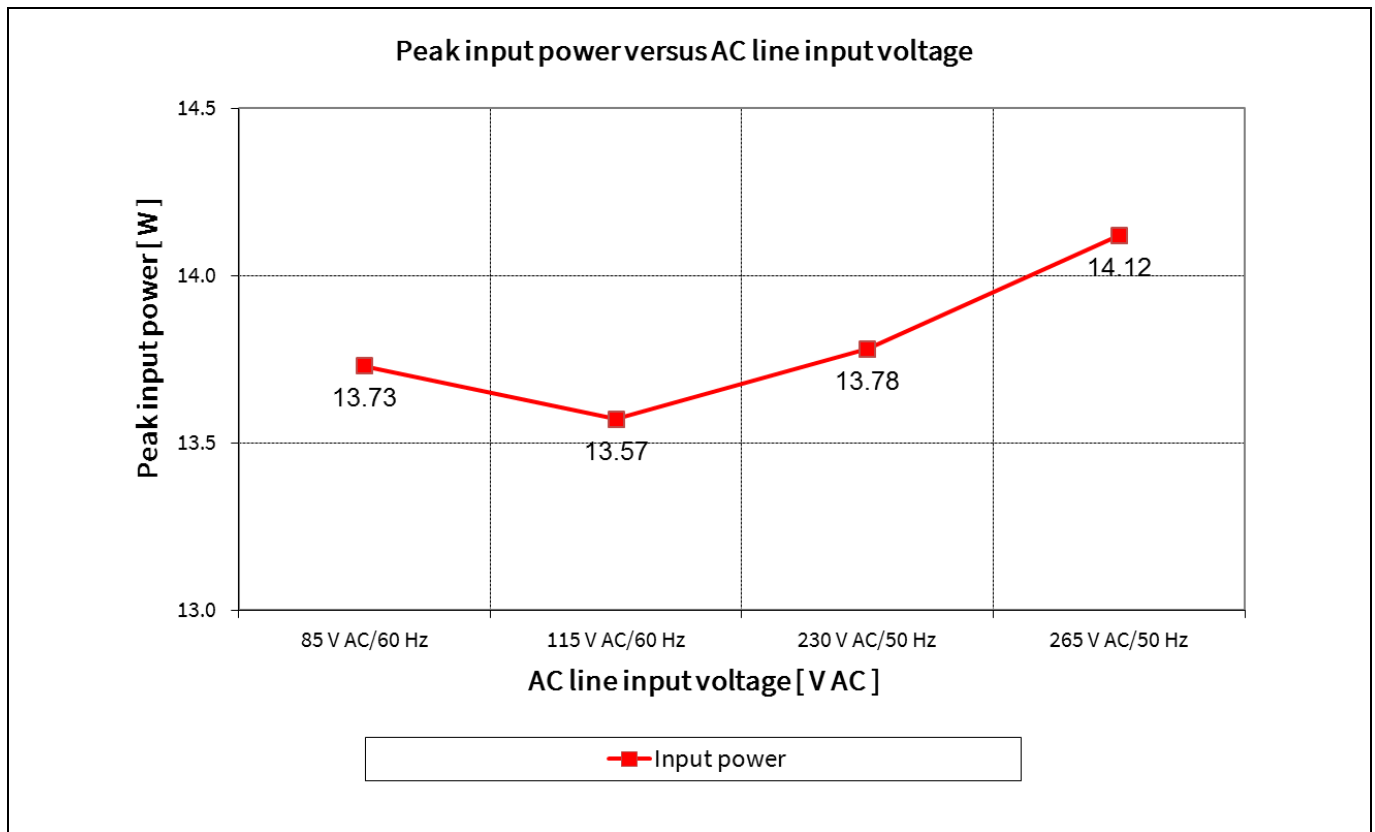


Figure 14 Maximum input power (before over-load protection) vs AC-line input voltage

## 9.6 Frequency reduction

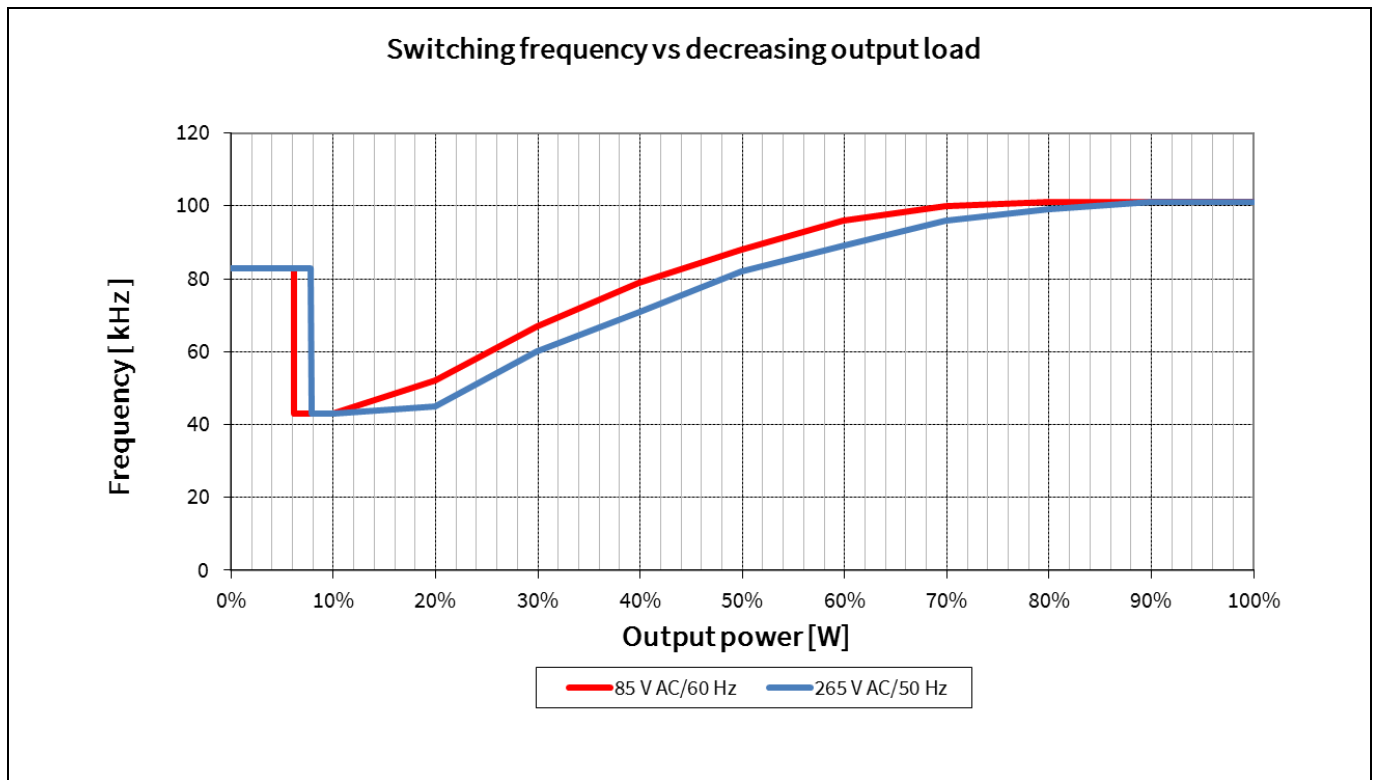


Figure 15 Frequency reduction curve vs output load

## 9.7 ESD immunity (EN 61000-4-2)

This system was subjected to a  $\pm 10$  kV ESD test according to EN 61000-4-2 special for both contact and air discharge. A test failure was defined as non-recoverable.

- Air discharge: pass  $\pm 10$  kV; contact discharge: pass  $\pm 10$  kV.

Table 6 System ESD test result

| Description  | ESD test | Level  | Number of strikes |                   | Test result |
|--|----------|--------|-------------------|-------------------|-------------|
|  |          |        | +V <sub>OUT</sub> | -V <sub>OUT</sub> |             |
| 115 V AC, 8 W<br>(12 V/26.7 $\Omega$ , 5 V/10 $\Omega$ ) | Contact  | +10 kV | 10                | 10                | PASS        |
|  |          | -10 kV | 10                | 10                | PASS        |
|  | Air      | +10 kV | 10                | 10                | PASS        |
|  |          | -10 kV | 10                | 10                | PASS        |
| 230 V AC, 8 W<br>(12 V/26.7 $\Omega$ , 5 V/10 $\Omega$ ) | Contact  | +10 kV | 10                | 10                | PASS        |
|  |          | -10 kV | 10                | 10                | PASS        |
|  | Air      | +10 kV | 10                | 10                | PASS        |
|  |          | -10 kV | 10                | 10                | PASS        |

## 9.8 Surge immunity (EN 61000-4-5)

This system was subjected to a surge immunity test ( $\pm 2$  kV DM and  $\pm 4$  kV CM) according to EN 61000-4-5. A test failure was defined as a non-recoverable.

- DM: pass  $\pm 2$  kV; CM: pass  $\pm 4$  kV.

## Measurement data and graphs

Table 7 System surge immunity test result

| Description  | Test | Level |                   | Number of strikes |     |      |      | Test result |
|--|------|-------|-------------------|-------------------|-----|------|------|-------------|
|  |      |       |                   | 0°                | 90° | 180° | 270° |             |
| 115 V AC, 8 W<br>(12 V/26.7 $\Omega$ , 5 V/10 $\Omega$ ) | DM   | +2 kV | L $\rightarrow$ N | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -2 kV | L $\rightarrow$ N | 3                 | 3   | 3    | 3    | PASS        |
|  | CM   | +4 kV | L $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | +4 kV | N $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -4 kV | L $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -4 kV | N $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
| 230 V AC, 8 W<br>(12 V/26.7 $\Omega$ , 5 V/10 $\Omega$ ) | DM   | +2 kV | L $\rightarrow$ N | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -2 kV | L $\rightarrow$ N | 3                 | 3   | 3    | 3    | PASS        |
|  | CM   | +4 kV | L $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | +4 kV | N $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -4 kV | L $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |
|  |      | -4 kV | N $\rightarrow$ G | 3                 | 3   | 3    | 3    | PASS        |

## 9.9 Conducted emissions (EN 55022 class B)

The conducted EMI was measured by Schaffner (SMR4503) and followed the test standard of EN 55022 (CISPR 22) class B. The reference board is tested at full load (7.9 W) using resistive load at input voltage of 115 V AC and 230 V AC.

Pass conducted emissions EN 55022 (CISPR 22) class B with 13.6 dB margin at low-line (115 V AC) and 10.4 dB margin at high-line (230 V AC).

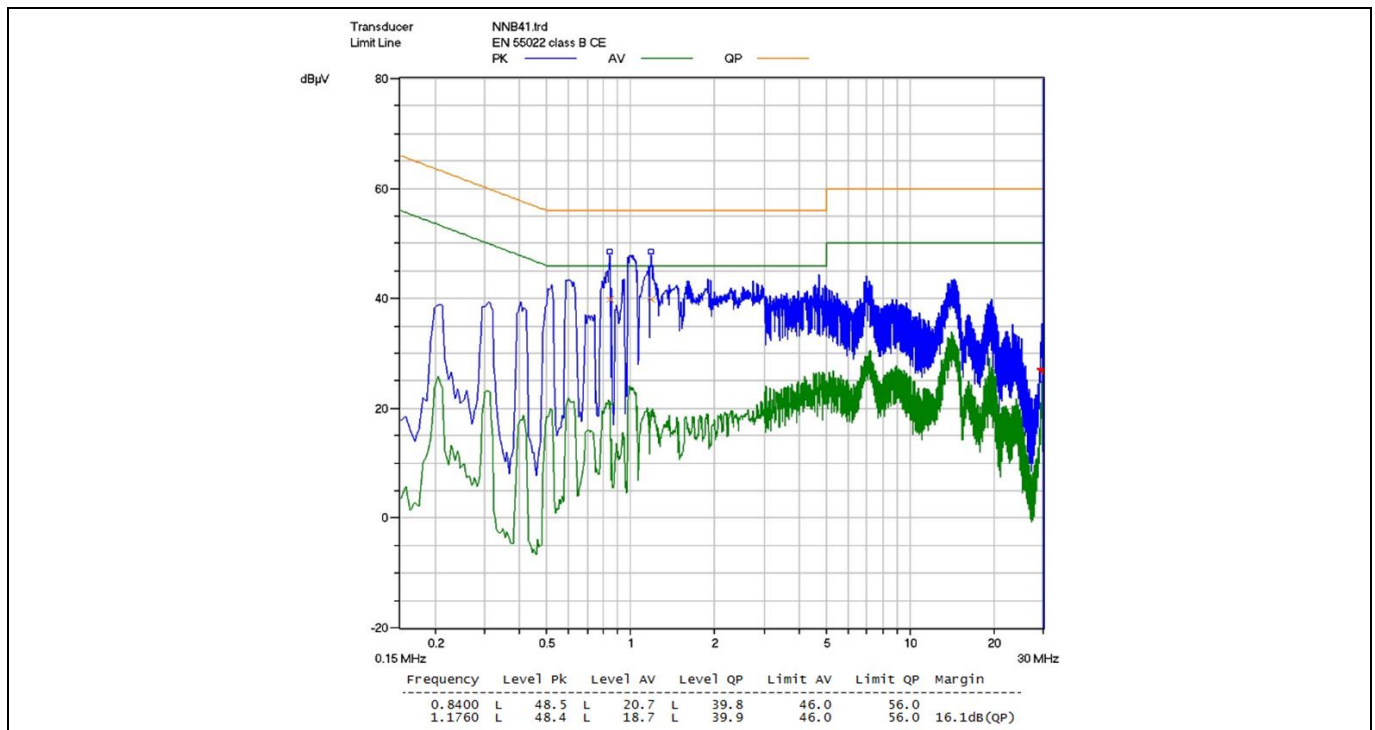


Figure 16 Conducted emissions (line) at 115 V AC and full load

Measurement data and graphs

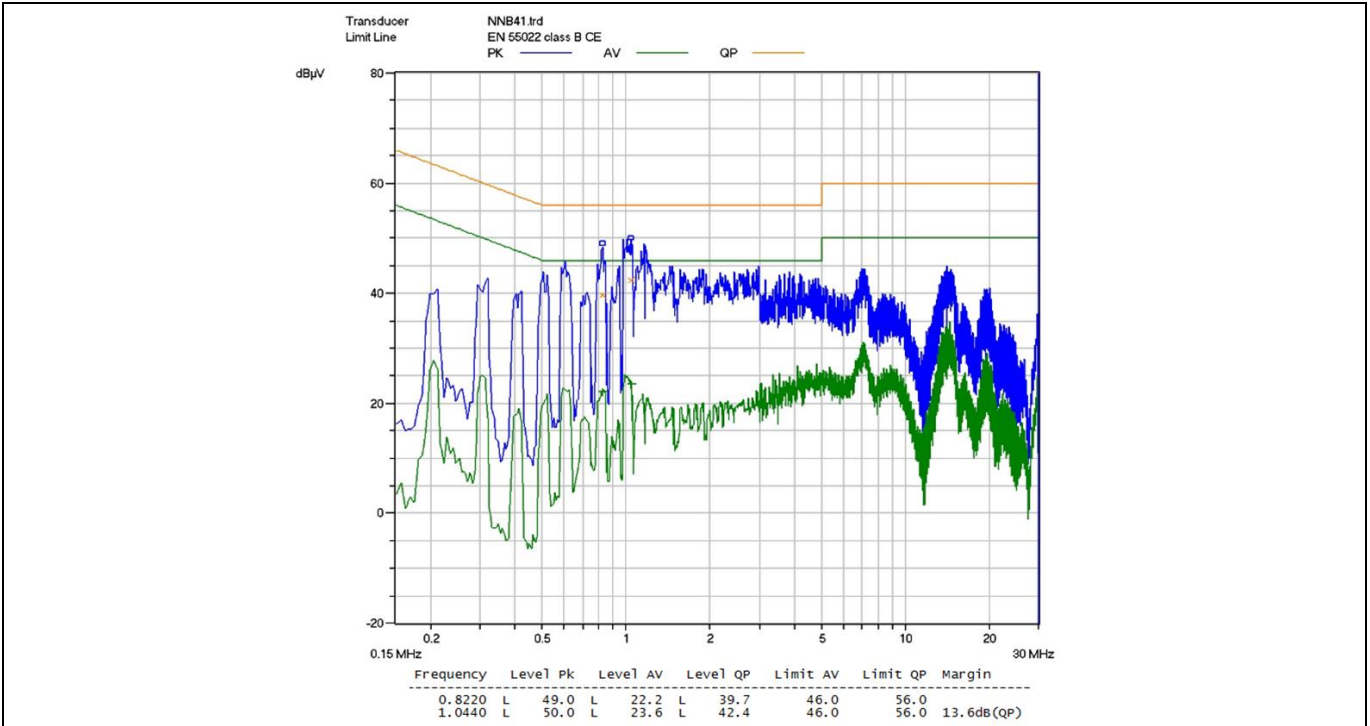


Figure 17 Conducted emissions (neutral) at 115 V AC and full load

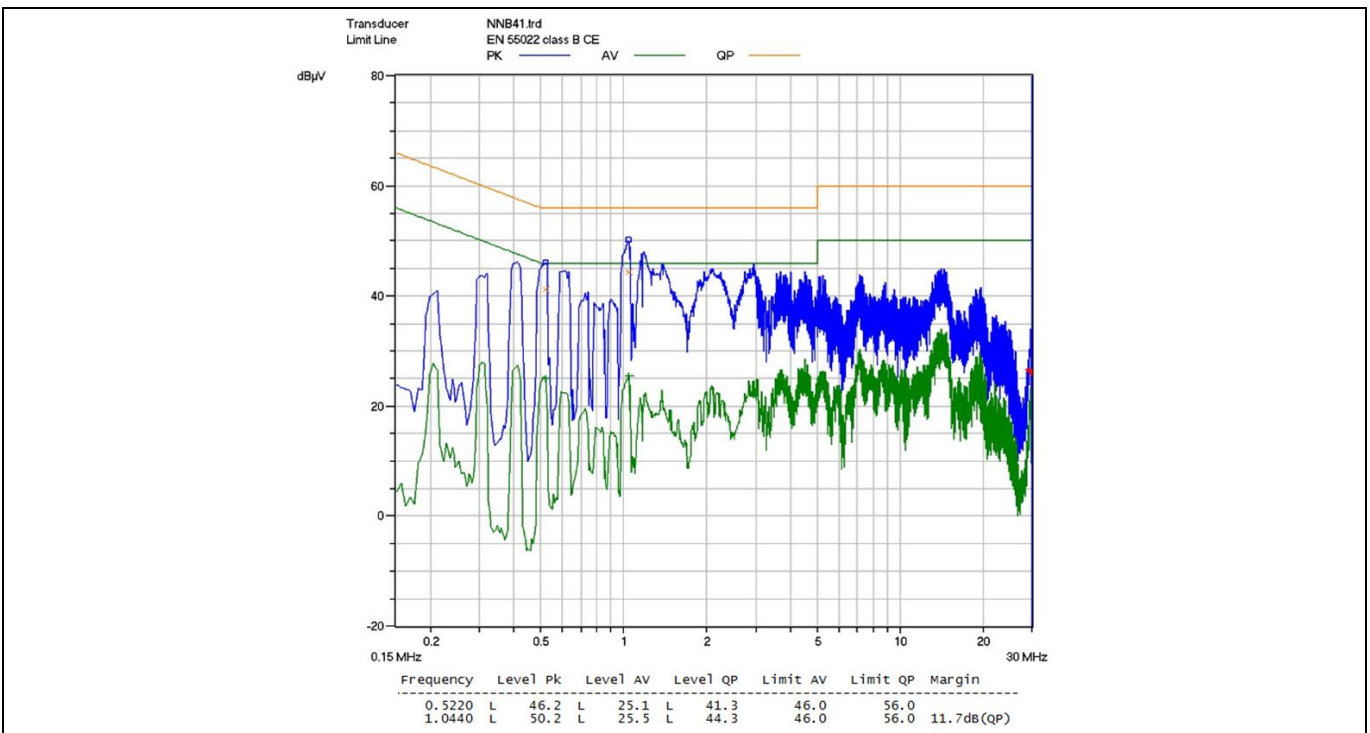


Figure 18 Conducted emissions (line) at 230 V AC and full load

## Measurement data and graphs

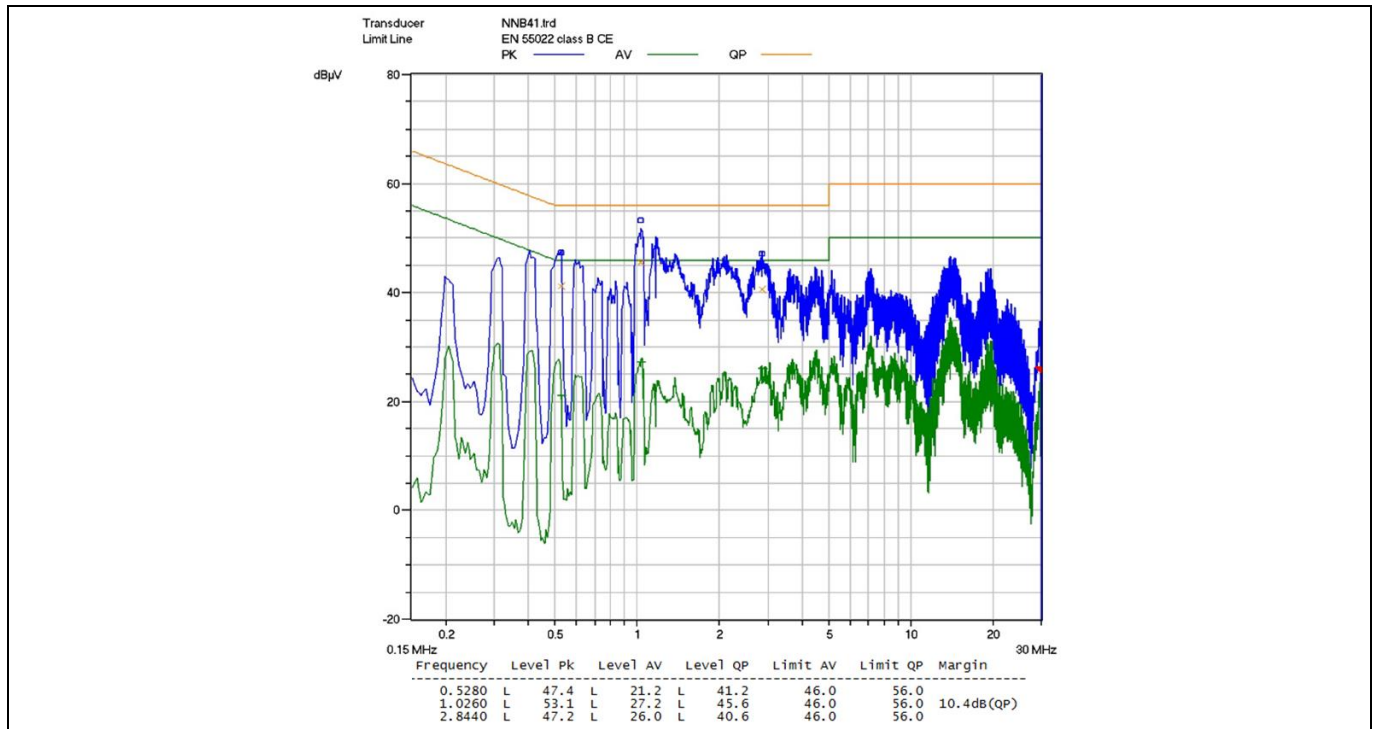


Figure 19 Conducted emissions (neutral) at 230 V AC and full load

## 9.10 Thermal measurement

The thermal test of the open-frame reference board was done using an infrared thermography camera (FLIR-T62101) at an ambient temperature of 25°C. The measurements were taken after one hour running at full load.

Table 8 Hottest components on the reference board

| No. | Components          | Temperature at 85 V AC (°C) | Temperature at 265 V AC (°C) |
|-----|---------------------|-----------------------------|------------------------------|
| 1   | D3 (+12 V diode)    | 55.6                        | 54.3                         |
| 2   | T1 (transformer)    | 56.8                        | 62.5                         |
| 3   | IC1 (ICE5AR4770BZS) | 54.3                        | 52.6                         |

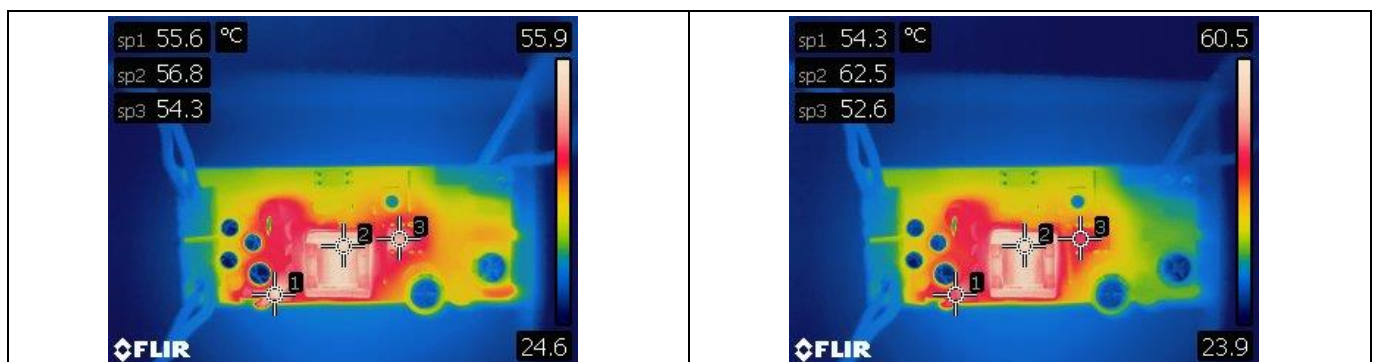


Figure 20 Top-side infrared thermal image of REF\_5AR4770BZS at 85 V AC (left) and 265 V AC (right) full load



## Waveforms and oscilloscope plots

## 10 Waveforms and oscilloscope plots

All waveforms and scope plots were recorded with a Teledyne LeCroy 606Zi oscilloscope.

## 10.1 Start-up at full load

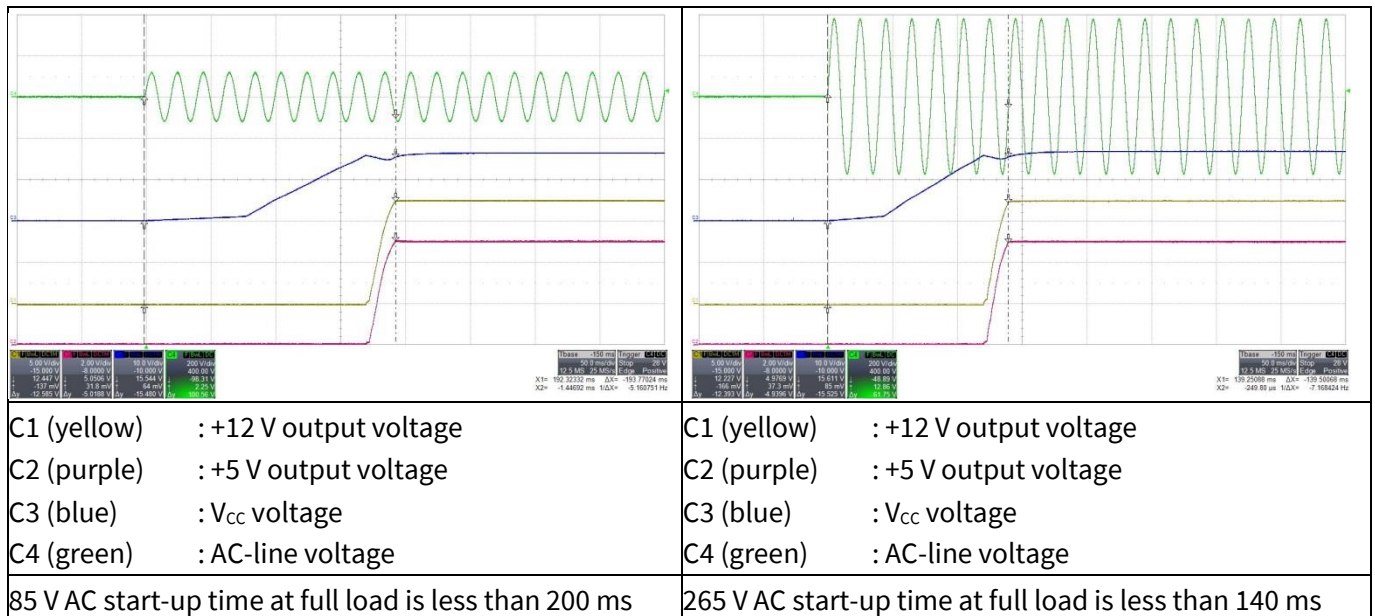


Figure 21 Start-up

## 10.2 Soft-start at full load

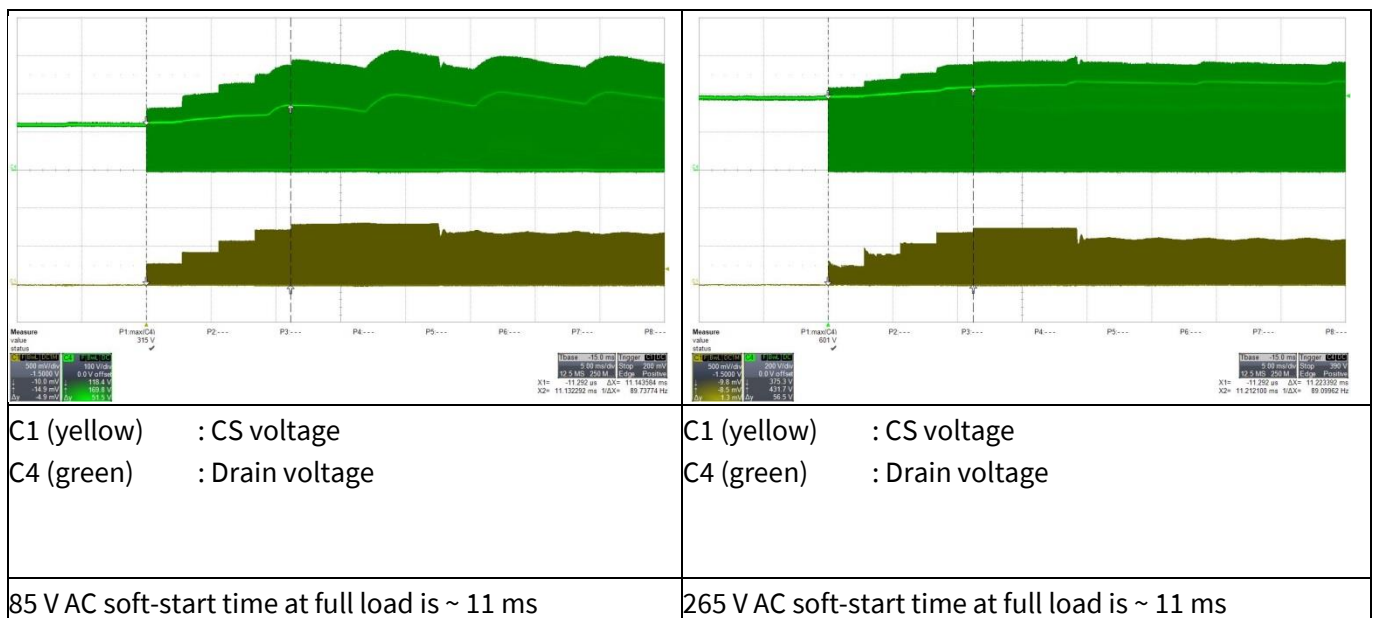


Figure 22 Soft-start

## Waveforms and oscilloscope plots

## 10.3 Drain and CS voltage at full load

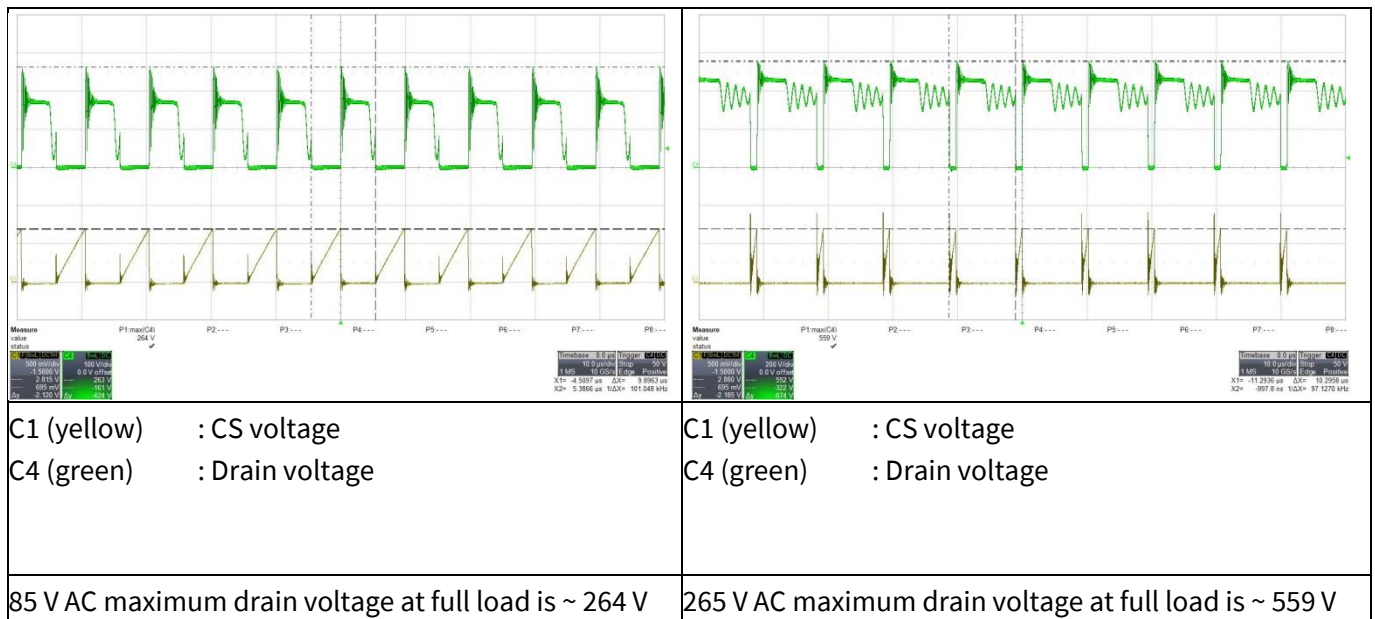


Figure 23 Drain and CS voltage

## 10.4 Frequency jittering at full load

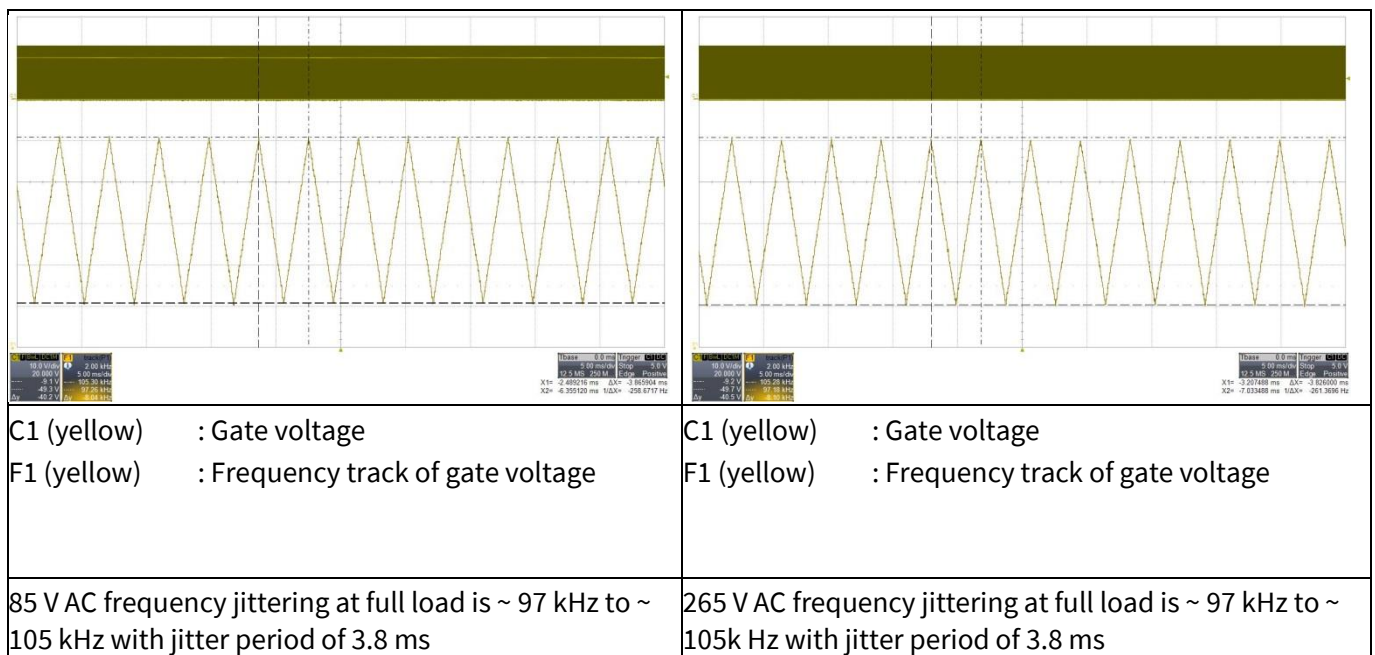
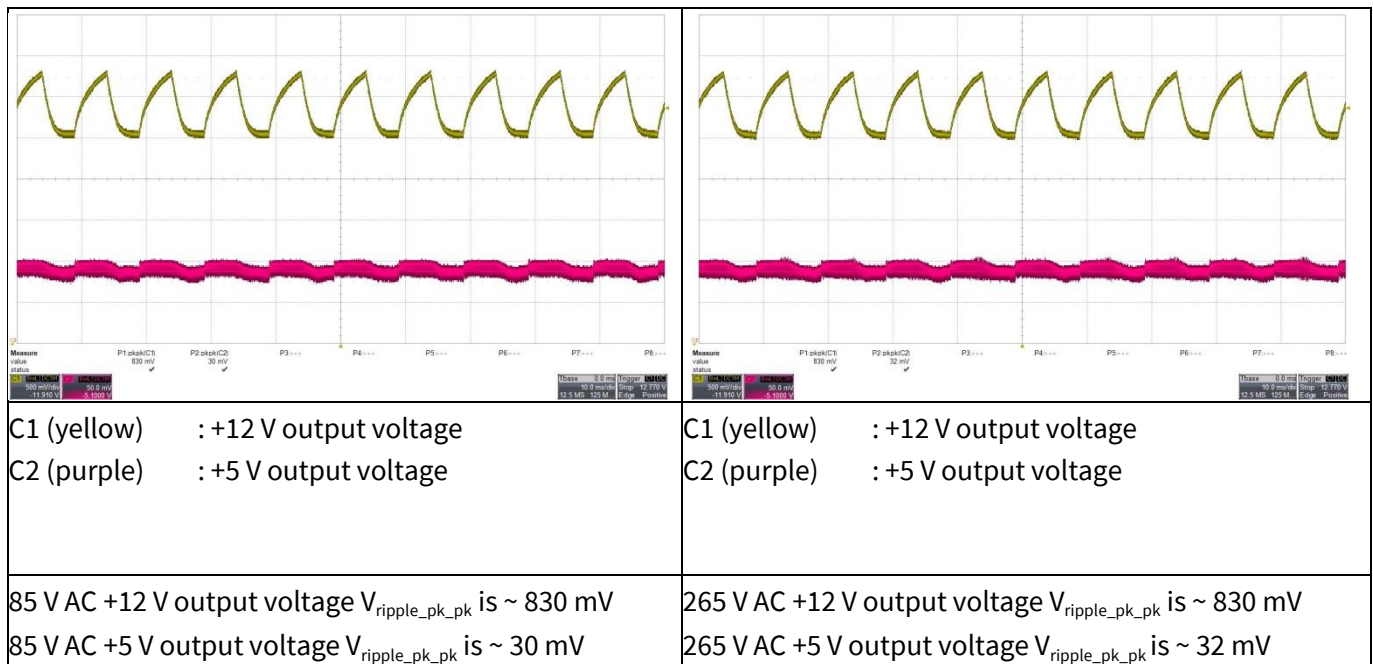


Figure 24 Frequency jittering

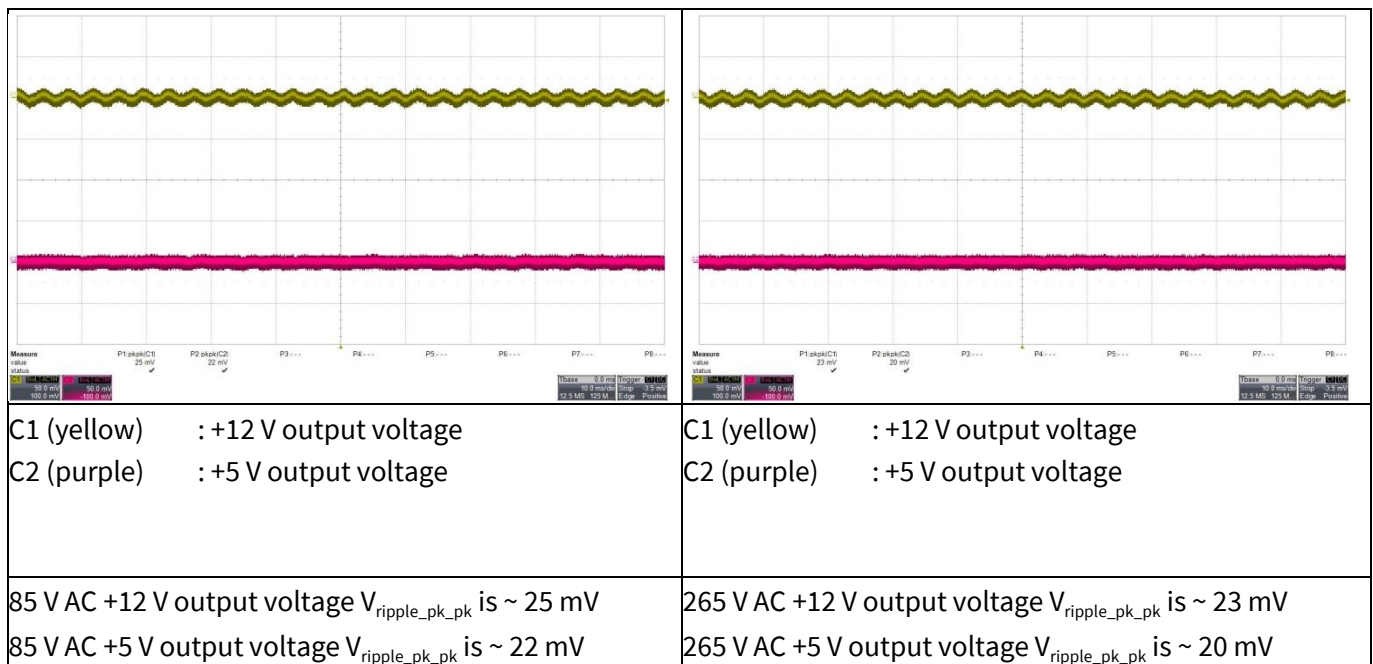
## Waveforms and oscilloscope plots

## 10.5 Load transient response (dynamic load from 10 percent to 100 percent)



**Figure 25** Load transient response with +12 V output load change from 10 percent to 100 percent at 0.4 A/ $\mu$ s slew rate, 100 Hz. +5 V output is fixed at 500 mA load. Probe terminals are decoupled with a 1  $\mu$ F electrolytic capacitor and a 0.1  $\mu$ F ceramic capacitor. Oscilloscope is BW filter limited to 20 MHz.

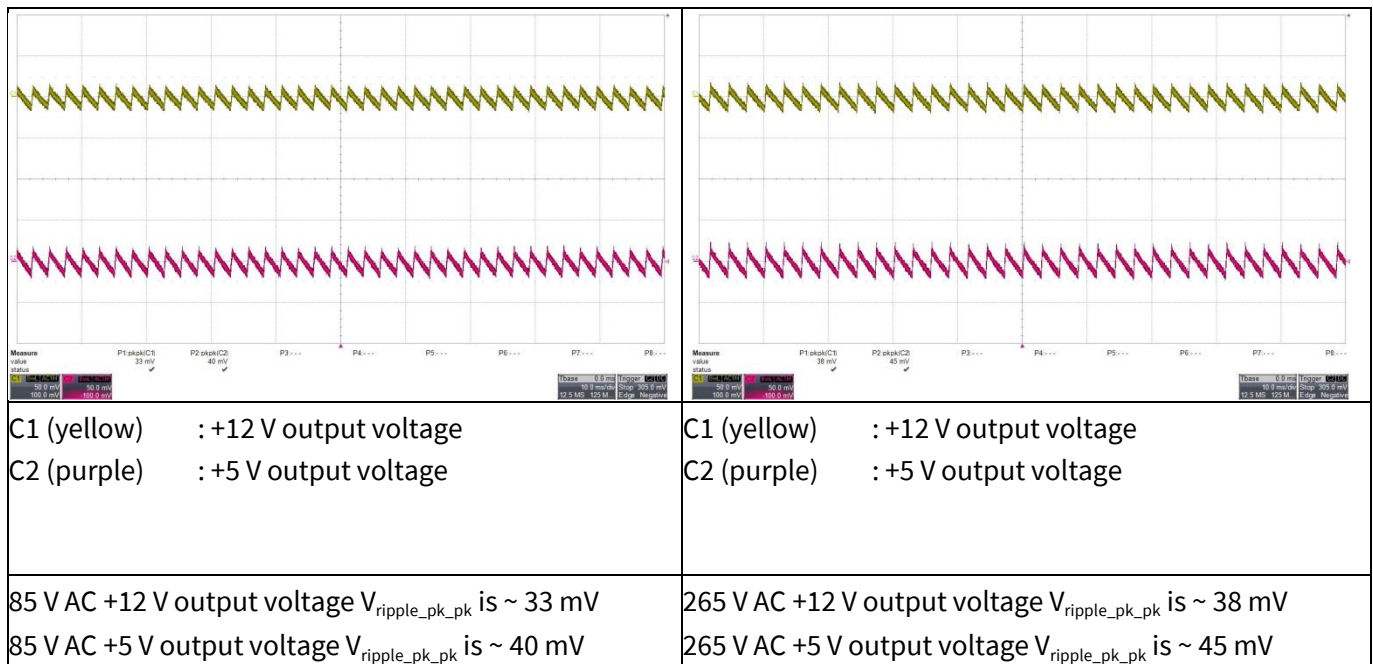
## 10.6 Output ripple voltage at full load



**Figure 26** Output ripple voltage at full load. Probe terminals are decoupled with a 1  $\mu$ F electrolytic capacitor and a 0.1  $\mu$ F ceramic capacitor. Oscilloscope is BW filter limited to 20 MHz.

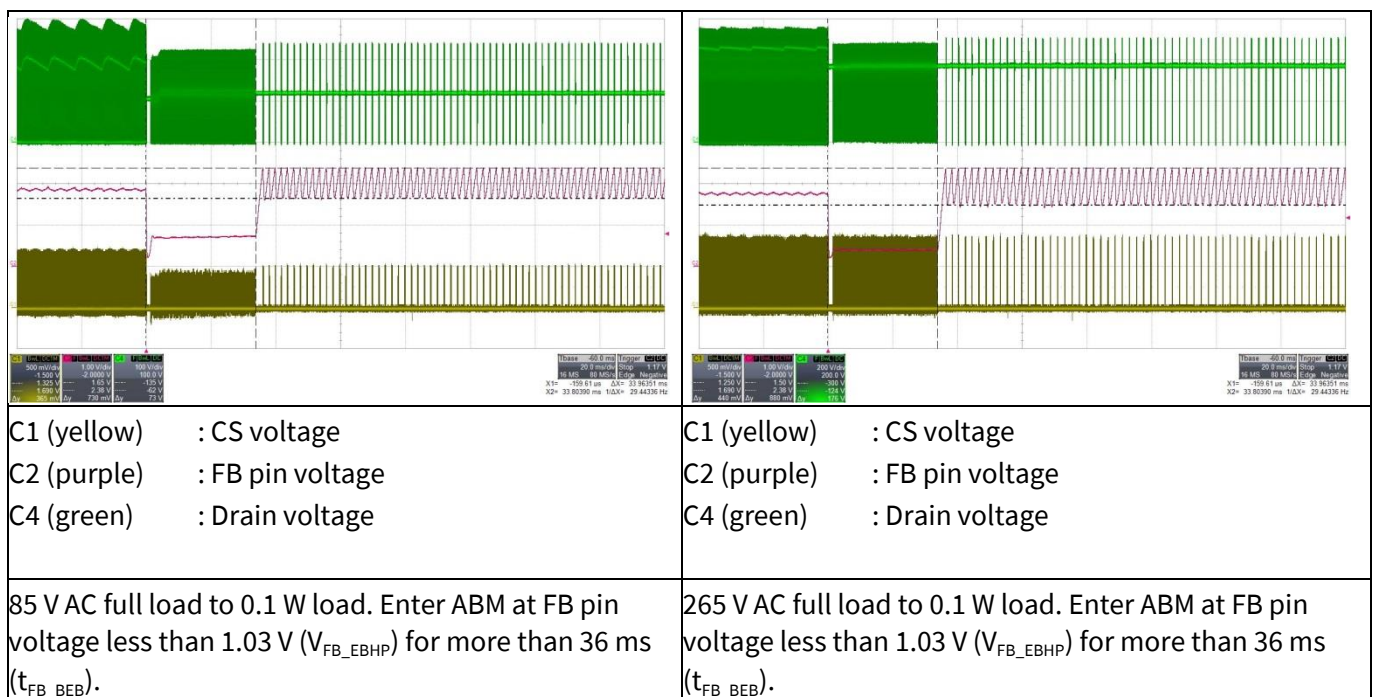
## Waveforms and oscilloscope plots

## 10.7 Output ripple voltage at ABM (0.1 W load)



**Figure 27** Output ripple voltage at 0.1 W load (+12 V/6 mA, +5 V/6 mA). Probe terminals are decoupled with a 1  $\mu$ F electrolytic capacitor and a 0.1  $\mu$ F ceramic capacitor. Oscilloscope is BW filter limited to 20 MHz.

## 10.8 Entering ABM



**Figure 28** Entering ABM. Output at full load to 0.1 W load (+12 V/6 mA, +5 V/6 mA).



### Waveforms and oscilloscope plots

#### 10.9 During ABM

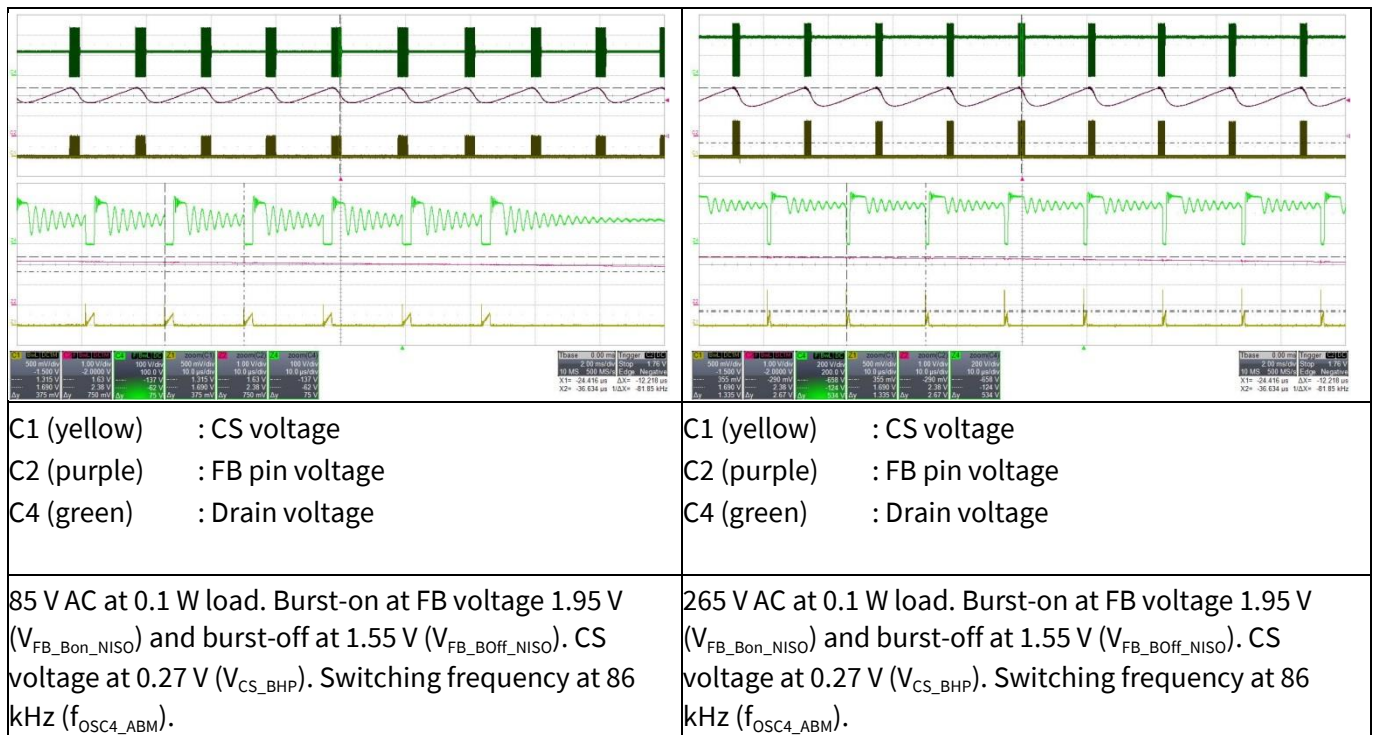


Figure 29 During ABM. Output at 0.1 W load (+12 V/6 mA, +5V/6 mA).

#### 10.10 Leaving ABM

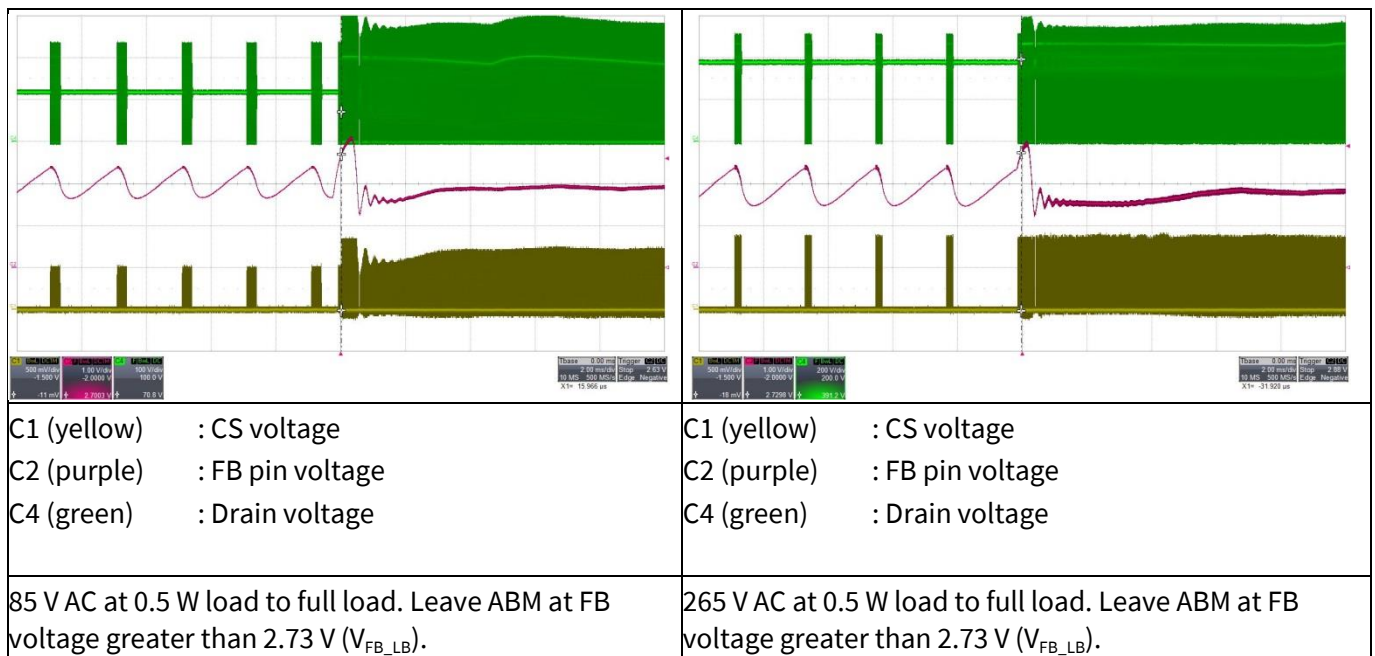


Figure 30 Leaving ABM. Output at 0.1 W load (+12 V/6 mA, +5 V/6 mA) to full load.

### Waveforms and oscilloscope plots

#### 10.11 $V_{CC}$ OVP/UV

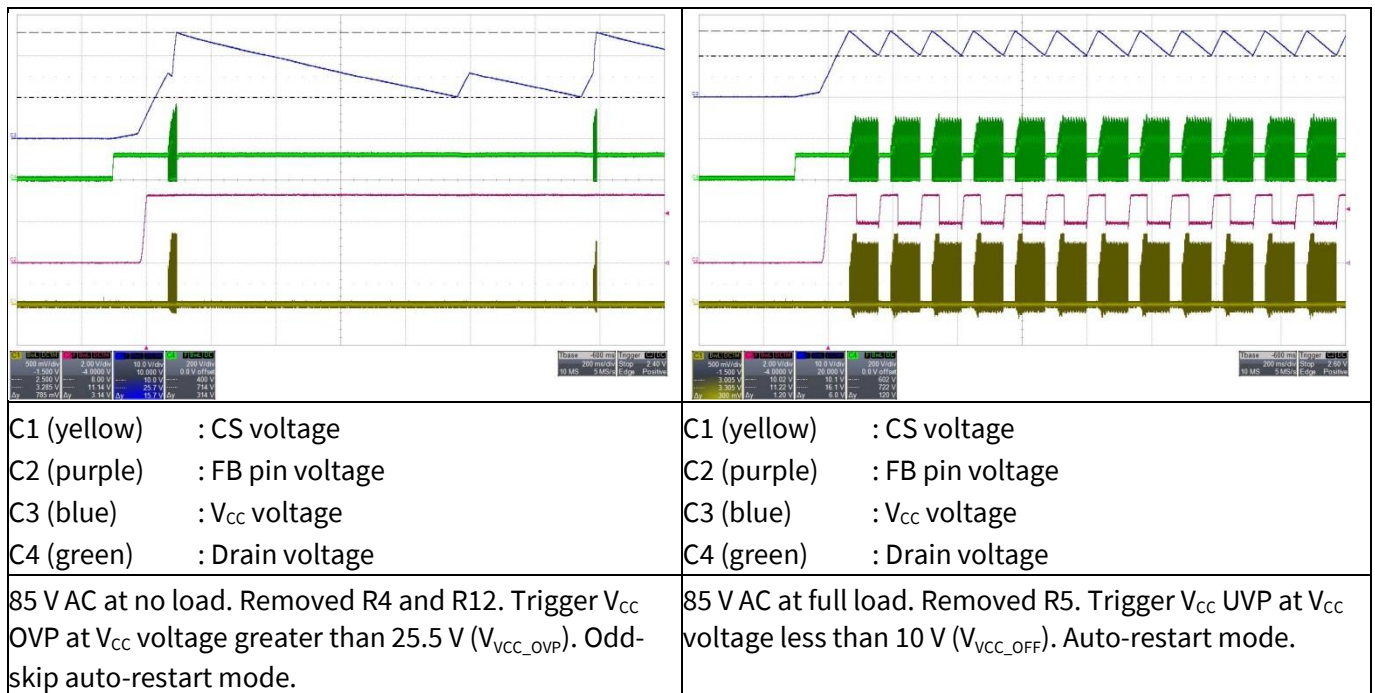


Figure 31  $V_{CC}$  OVP/UV

#### 10.12 Over-load protection

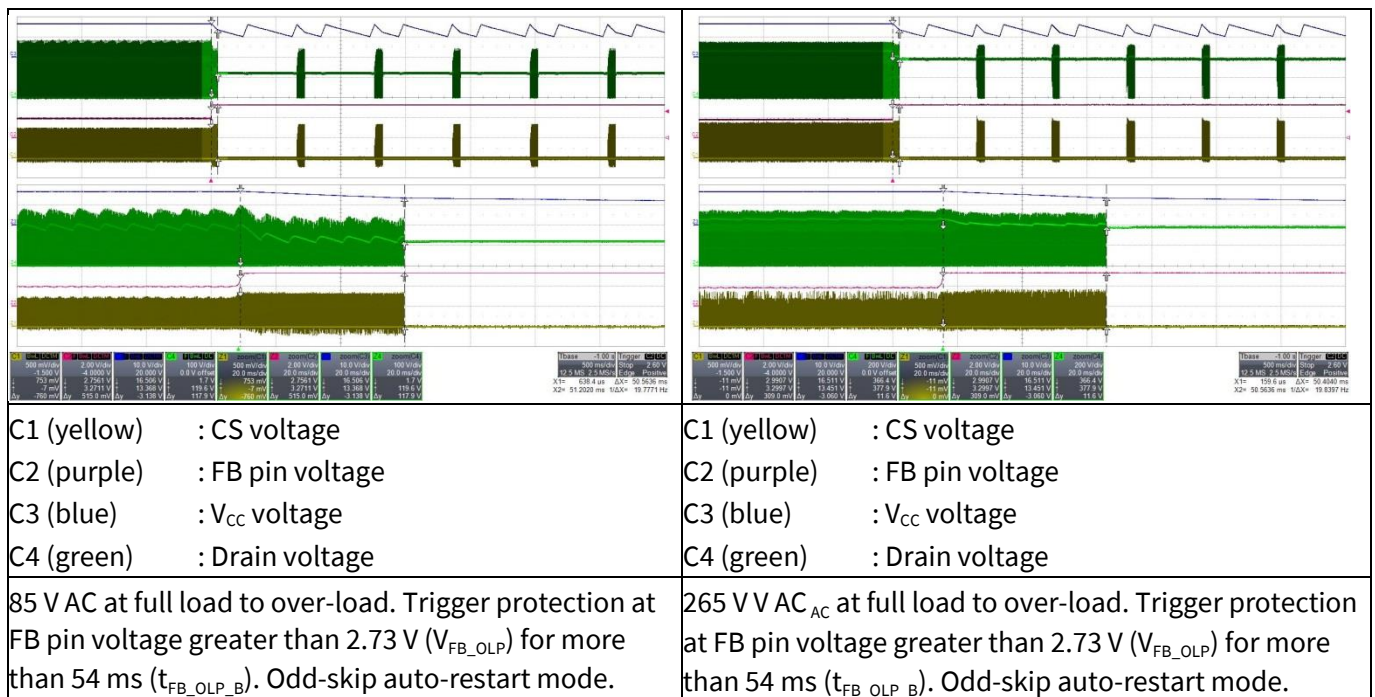


Figure 32 Over-load protection. Load increased at +12 V to 2 A to trigger protection.

Waveforms and oscilloscope plots

10.13  $V_{CC}$  short-to-GND

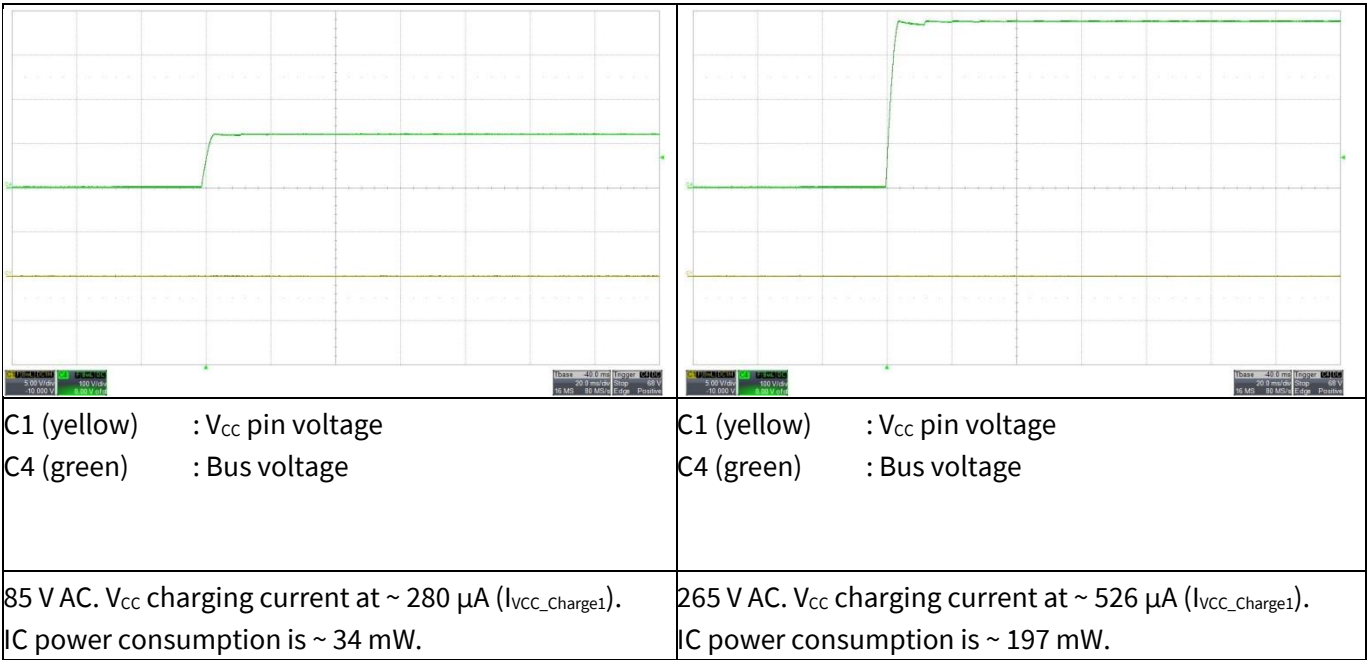


Figure 33  $V_{CC}$  short-to-GND.  $V_{CC}$  charging current measured with a digital multimeter.



## Appendix A: Transformer design and spreadsheet [3]

## 11 Appendix A: Transformer design and spreadsheet [3]

## Calculation tool for flyback converter using fifth-generation fixed-frequency CoolSET™ (version 1.0)

|             |   |
|-------------|---|
| Project     | 85 ~ 265 V AC dual-output 8 W isolated flyback power supply |
| Application | Auxiliary power supply for air-conditioner                  |
| CoolSET™    | ICE5AR4770BZS   |
| Date        | 6 Feb 18  |
| Revision    | V 1.0   |

Notes:

Enter design variables in orangecolored cells

Read design results in green coloured cells

| Description                             |   | Eq. #   | Parameter        | Unit | Value         |
|---|---|---------|------------------|------|---------------|
| <b>Input, output, CoolSET™ specs</b>    |   |         |                  |      |               |
| <b>Line input</b>                       |   |         |                  |      |               |
| Input                                   | Minimum AC input voltage                      |         | $V_{ACMin}$      | [V]  | 85            |
| Input                                   | Maximum AC input voltage                      |         | $V_{ACMax}$      | [V]  | 265           |
| Input                                   | Line frequency                                |         | $f_{AC}$         | [Hz] | 60            |
| Input                                   | Bus capacitor DC ripple voltage               |         | $V_{DCRipple}$   | [V]  | 37            |
| <b>Output 1 specs</b>                   |   |         |                  |      |               |
| Input                                   | Output voltage 1                              |         | $V_{Out1}$       | [V]  | 12            |
| Input                                   | Output current 1                              |         | $I_{Out1}$       | [A]  | 0.45          |
| Input                                   | Forward voltage of output diode 1             |         | $V_{FOut1}$      | [V]  | 0.6           |
| Input                                   | Output ripple voltage 1                       |         | $V_{OutRipple1}$ | [V]  | 100           |
| Result                                  | Output power 1                                | Eq. 001 | $P_{Out1}$       | [W]  | 5.4           |
| Result                                  | Output load weight 1                          | Eq. 004 | $K_{L1}$         |      | 0.68          |
| <b>Output 2 specs</b>                   |   |         |                  |      |               |
| Input                                   | Output voltage 2                              |         | $V_{Out2}$       | [V]  | 5             |
| Input                                   | Output current 2                              |         | $I_{Out2}$       | [A]  | 0.5           |
| Input                                   | Forward voltage of output diode 2             |         | $V_{FOut2}$      | [V]  | 0.2           |
| Input                                   | Output ripple voltage 2                       |         | $V_{OutRipple2}$ | [V]  | 100           |
| Result                                  | Output power 2                                | Eq. 002 | $P_{Out2}$       | [W]  | 2.5           |
| Result                                  | Output load weight 2                          | Eq. 005 | $K_{L2}$         |      | 0.32          |
| <b>Auxiliary</b>                        |   |         |                  |      |               |
| Input                                   | $V_{CC}$ voltage                              |         | $V_{VCC}$        | [V]  | 14            |
| Input                                   | Forward voltage of $V_{CC}$ diode (D1)        |         | $V_{FVCC}$       | [V]  | 0.6           |
| <b>Power</b>                            |   |         |                  |      |               |
| Input                                   | Efficiency                                    |         | $\eta$           |      | 0.85          |
| Result                                  | Nominal output power                          | Eq. 003 | $P_{OutNom}$     | [W]  | 7.90          |
| Input                                   | Maximum output power for over-load protection |         | $P_{OutMax}$     | [W]  | 10            |
| Result                                  | Maximum input power for over-load protection  | Eq. 006 | $P_{InMax}$      | [W]  | 12.24         |
| Input                                   | Minimum output power                          |         | $P_{OutMin}$     | [W]  | 2             |
| <b>Controller/CoolSET™</b>              |   |         |                  |      |               |
|   | Controller/CoolSET™                           |         |                  |      | ICE5AR4770BZS |
| Input                                   | Switching frequency                           |         | $f_s$            | [Hz] | 100000        |
| Input                                   | Targeted max. drain source voltage            |         | $V_{DSMax}$      | [V]  | 700           |
| Input                                   | Max. ambient temperature                      |         | $T_{amax}$       | [°C] | 50            |
| <b>Diode bridge and input capacitor</b> |   |         |                  |      |               |
| <b>Diode bridge</b>                     |   |         |                  |      |               |
| Input                                   | Power factor                                  |         | $\cos\phi$       |      | 0.6           |
| Result                                  | Maximum AC input current                      | Eq. 007 | $I_{ACRMS}$      | [A]  | 0.240         |
| Result                                  | Peak voltage at $V_{ACMax}$                   | Eq. 008 | $V_{DCMaxPk}$    | [V]  | 374.77        |

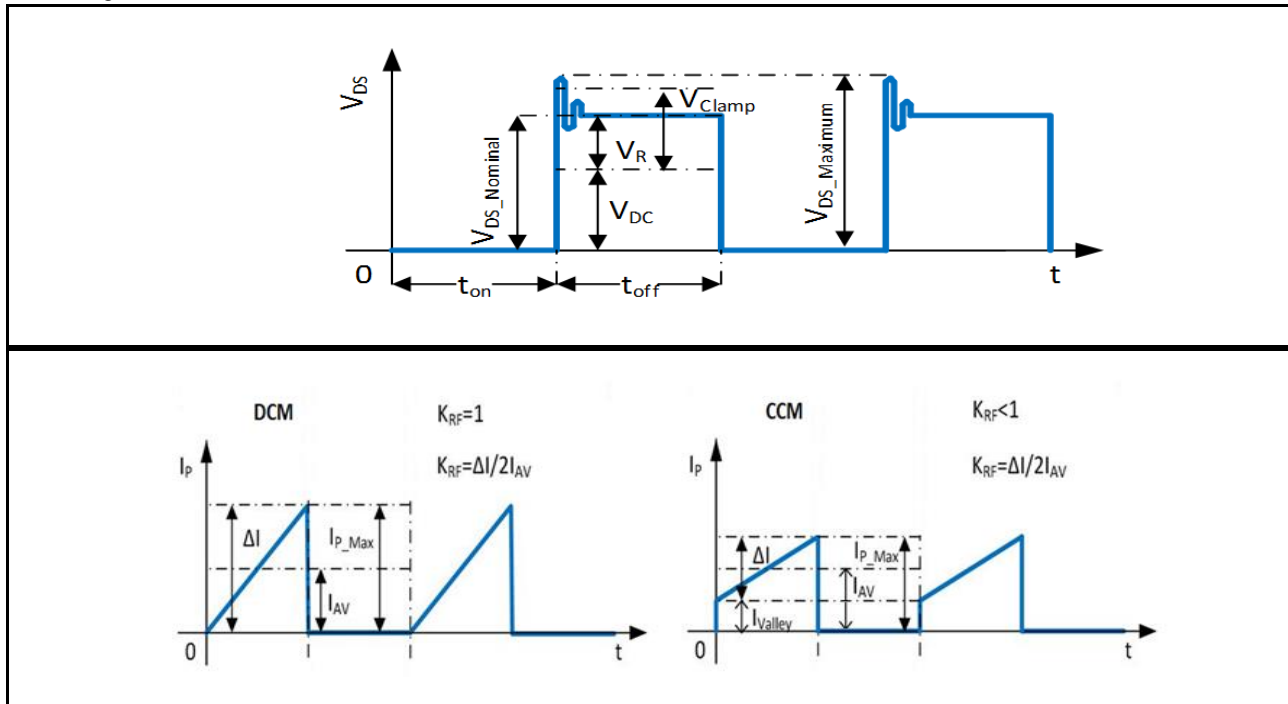
## Appendix A: Transformer design and spreadsheet [3]

## Input capacitor

|        |  |         |                   |             |        |
|--------|--|---------|-------------------|-------------|--------|
| Result | Peak voltage at $V_{AC_{Min}}$                         | Eq. 009 | $V_{DC_{MinPk}}$  | [V]         | 120.21 |
| Result | Selected minimum DC input voltage                      | Eq. 010 | $V_{DC_{MinSet}}$ | [V]         | 83.21  |
| Result | Discharging time at each half-line cycle               | Eq. 011 | $T_D$             | [ms]        | 6.19   |
| Result | Required energy at discharging time of input capacitor | Eq. 012 | $W_{in}$          | [Ws]        | 0.08   |
| Result | Calculated input capacitor                             | Eq. 013 | $C_{inCal}$       | [ $\mu F$ ] | 20.14  |
| Input  | Select input capacitor ( $C_1 + C_2$ )                 |         | $C_{in}$          | [ $\mu F$ ] | 20     |
| Result | Calculated minimum DC input voltage                    | Eq. 015 | $V_{DC_{Min}}$    | [V]         | 82.89  |

## Transformer design

## Drain voltage and current waveform



## Primary inductance and winding currents

|        |                                 |         |               |     |          |
|--------|---------------------------------|---------|---------------|-----|----------|
| Input  | Reflection voltage              |         | $V_{RSET}$    | [V] | 84       |
| Result | Maximum duty cycle              | Eq. 016 | $D_{Max}$     |     | 0.50     |
| Input  | Select current ripple factor    |         | $K_{RF}$      |     | 1        |
| Result | Primary inductance              | Eq. 017 | $L_P$         | [H] | 7.11E-04 |
| Result | Primary turn-on average current | Eq. 018 | $I_{AV}$      | [A] | 0.29     |
| Result | Primary peak-to-peak current    | Eq. 019 | $\Delta I$    | [A] | 0.59     |
| Result | Primary peak current            | Eq. 020 | $I_{P_{Max}}$ | [A] | 0.59     |
| Result | Primary valley current          | Eq. 021 | $I_{Valley}$  | [A] | 0.00     |
| Result | Primary RMS current             | Eq. 022 | $I_{PRMS}$    | [A] | 0.240    |

## Select core type

|        |                        |  |           |                    |            |
|--------|------------------------|--|-----------|--------------------|------------|
| Input  | Select core type       |  |           |                    | 10         |
| Result | Core type              |  |           |                    | EE16/8/5   |
| Result | Core material          |  |           |                    | TP4A (TDG) |
| Result | Maximum flux density   |  | $B_{Max}$ | [T]                | 0.3        |
| Result | Cross-sectional area   |  | $A_e$     | [mm <sup>2</sup> ] | 20.1       |
| Result | Bobbin width           |  | BW        | [mm]               | 9.5        |
| Result | Winding cross-section  |  | $A_N$     | [mm <sup>2</sup> ] | 22.3       |
| Result | Average length of turn |  | $l_N$     | [mm]               | 34         |

## Winding calculation

|        |  |         |             |       |       |
|--------|--|---------|-------------|-------|-------|
| Result | Calculated minimum number of primary turns | Eq. 023 | $N_{PCal}$  | Turns | 69.19 |
| Input  | Select number of primary turns             |         | $N_P$       | Turns | 80    |
| Result | Calculated number of secondary 1 turns     | Eq. 024 | $N_{S1Cal}$ | Turns | 12.00 |
| Input  | Select number of secondary 1 turns         |         | $N_{S1}$    | Turns | 12    |

## Appendix A: Transformer design and spreadsheet [3]

|        |  |         |              |       |       |
|--------|--|---------|--------------|-------|-------|
| Result | Calculated number of secondary 2 turns | Eq. 025 | $N_{S2Cal}$  | Turns | 4.95  |
| Input  | Select number of secondary 2 turns     |         | $N_{S2}$     | Turns | 5     |
| Result | Calculated number of auxiliary turns   | Eq. 026 | $N_{VccCal}$ | Turns | 13.90 |
| Input  | Select number of auxiliary turns       |         | $N_{Vcc}$    | Turns | 14    |
| Result | Calculated $V_{cc}$ voltage            | Eq. 027 | $V_{VccCal}$ | [V]   | 14.10 |

## Post calculation

|        |  |         |                |     |       |
|--------|--|---------|----------------|-----|-------|
| Result | Primary to secondary 1 turns ratio         | Eq. 028 | $N_{PS1}$      |     | 6.67  |
| Result | Primary to secondary 2 turns ratio         | Eq. 029 | $N_{PS2}$      |     | 16.00 |
| Result | Post calculated reflected voltage          | Eq. 030 | $V_{RPost}$    | [V] | 84.00 |
| Result | Post calculated maximum duty cycle         | Eq. 031 | $D_{MaxPost}$  |     | 0.50  |
| Result | Duty cycle prime                           | Eq. 032 | $D_{Max}^1$    |     | 0.50  |
| Result | Actual flux density                        | Eq. 033 | $B_{MaxAct}$   | [T] | 0.259 |
| Result | Maximum DC input voltage for CCM operation | Eq. 034 | $V_{DCmaxCCM}$ | [V] | 82.89 |

## Transformer winding design

|        |                                     |         |             |                    |      |
|--------|-------------------------------------|---------|-------------|--------------------|------|
| Input  | Margin according to safety standard |         | M           | [mm]               | 0    |
| Input  | Copper space factor                 |         | $f_{Cu}$    |                    | 0.4  |
| Result | Effective bobbin window             | Eq. 035 | $BW_E$      | [mm]               | 9.5  |
| Result | Effective winding cross-section     | Eq. 036 | $A_{Ne}$    | [mm <sup>2</sup> ] | 22.3 |
| Input  | Primary winding area factor         |         | $AF_{NP}$   |                    | 0.50 |
| Input  | Secondary 1 winding area factor     |         | $AF_{NS1}$  |                    | 0.30 |
| Input  | Secondary 2 winding area factor     |         | $AF_{NS2}$  |                    | 0.15 |
| Input  | Auxiliary winding area factor       |         | $AF_{NVcc}$ |                    | 0.05 |

## Primary winding

|        |   |         |              |                      |        |
|--------|---|---------|--------------|----------------------|--------|
| Result | Calculated wire copper cross-sectional area | Eq. 037 | $A_{PCal}$   | [mm <sup>2</sup> ]   | 0.0558 |
| Result | Calculated maximum wire size                | Eq. 038 | $AWG_{PCal}$ |                      | 30     |
| Input  | Select wire size                            |         | $AWG_P$      |                      | 33     |
| Input  | Select number of parallel wire              |         | $n_{WP}$     |                      | 1      |
| Result | Wire copper diameter                        | Eq. 039 | $d_P$        | [mm]                 | 0.18   |
| Result | Wire copper cross-sectional area            | Eq. 040 | $A_P$        | [mm <sup>2</sup> ]   | 0.0259 |
| Result | Wire current density                        | Eq. 041 | $S_P$        | [A/mm <sup>2</sup> ] | 9.29   |
| Input  | Insulation thickness                        |         | $INS_P$      | [mm]                 | 0.04   |
| Result | Turns per layer                             | Eq. 042 | $N_{LP}$     | Turns/layer          | 36     |
| Result | Number of layers                            | Eq. 043 | $L_{NP}$     | Layers               | 3      |

## Secondary 1 winding

|        |   |         |               |                      |        |
|--------|---|---------|---------------|----------------------|--------|
| Result | Calculated wire copper cross-sectional area | Eq. 044 | $A_{NS1Cal}$  | [mm <sup>2</sup> ]   | 0.2230 |
| Result | Calculated maximum wire size                | Eq. 045 | $AWG_{S1Cal}$ |                      | 24     |
| Input  | Select wire size                            |         | $AWG_{S1}$    |                      | 27     |
| Input  | Select number of parallel wire              |         | $n_{WS1}$     |                      | 1      |
| Result | Wire copper diameter                        | Eq. 046 | $d_{S1}$      | [mm]                 | 0.3629 |
| Result | Wire copper cross-sectional area            | Eq. 047 | $A_{S1}$      | [mm <sup>2</sup> ]   | 0.1034 |
| Result | Peak current                                | Eq. 048 | $I_{S1Max}$   | [A]                  | 2.6728 |
| Result | RMS current                                 | Eq. 049 | $I_{S1RMS}$   | [A]                  | 1.0875 |
| Result | Wire current density                        | Eq. 050 | $S_{S1}$      | [A/mm <sup>2</sup> ] | 10.51  |
| Input  | Insulation thickness                        |         | $INS_{S1}$    | [mm]                 | 0.04   |
| Result | Turns per layer                             | Eq. 051 | $N_{LS1}$     | Turns/layer          | 12     |
| Result | Number of layers                            | Eq. 052 | $L_{NS1}$     | Layers               | 1      |

## Secondary 2 winding

|        |   |         |               |                    |        |
|--------|---|---------|---------------|--------------------|--------|
| Result | Calculated wire copper cross-sectional area | Eq. 053 | $A_{NS2Cal}$  | [mm <sup>2</sup> ] | 0.2676 |
| Result | Calculated maximum wire size                | Eq. 054 | $AWG_{S2Cal}$ |                    | 23     |
| Input  | Select wire size                            |         | $AWG_{S2}$    |                    | 27     |
| Input  | Select number of parallel wire              |         | $n_{WS2}$     |                    | 2      |
| Result | Wire copper diameter                        | Eq. 055 | $d_{S2}$      | [mm]               | 0.3629 |
| Result | Wire copper cross-sectional area            | Eq. 056 | $A_{S2}$      | [mm <sup>2</sup> ] | 0.2069 |
| Result | Peak current                                | Eq. 057 | $I_{S2Max}$   | [A]                | 2.9698 |

## Appendix A: Transformer design and spreadsheet [3]

|        |                      |         |             |                      |        |
|--------|----------------------|---------|-------------|----------------------|--------|
| Result | RMS current          | Eq. 058 | $I_{S2RMS}$ | [A]                  | 1.2084 |
| Result | Wire current density | Eq. 059 | $S_{S2}$    | [A/mm <sup>2</sup> ] | 5.84   |
| Input  | Insulation thickness |         | $INS_{S2}$  | [mm]                 | 0.04   |
| Result | Turns per layer      | Eq. 060 | $NL_{S2}$   | Turns/layer          | 10     |
| Result | Number of layers     | Eq. 061 | $Ln_{S2}$   | Layers               | 1      |

## RCD clamper and CS resistor

## RCD clamper circuit

|        |                                      |         |                |           |          |
|--------|--------------------------------------|---------|----------------|-----------|----------|
| Input  | Leakage inductance percentage        |         | $L_{LK\%}$     | [Percent] | 2.5      |
| Result | Leakage inductance                   | Eq. 062 | $L_{LK}$       | [H]       | 1.78E-05 |
| Result | Clamping voltage                     | Eq. 063 | $V_{Clamp}$    | [V]       | 241.23   |
| Result | Calculated clamping capacitor        | Eq. 064 | $C_{ClampCal}$ | [nF]      | 0.08     |
| Input  | Select clamping capacitor value (C6) |         | $C_{Clamp}$    | [nF]      | 0.47     |
| Result | Calculated clamping resistor         | Eq. 065 | $R_{ClampCal}$ | [kΩ]      | 322.7    |
| Input  | Select clamping resistor value (R6)  |         | $R_{Clamp}$    | [kΩ]      | 240      |

## CS resistor

|        |                                   |         |             |     |      |
|--------|-----------------------------------|---------|-------------|-----|------|
| Input  | CS threshold value from datasheet |         | $V_{CS\_N}$ | [V] | 0.8  |
| Result | Calculated CS resistor (R1A/R1B)  | Eq. 066 | $R_{sense}$ | [Ω] | 1.36 |

## Output rectifier

## Secondary 1 output rectifier

|        |   |         |                   |       |          |
|--------|---|---------|-------------------|-------|----------|
| Result | Diode reverse voltage                             | Eq. 067 | $V_{RDiode1}$     | [V]   | 68.21    |
| Result | Diode RMS current                                 |         | $I_{S1RMS}$       | [A]   | 1.09     |
| Input  | Max. voltage undershoot at output capacitor       |         | $\Delta V_{Out1}$ | [V]   | 0.3      |
| Input  | Number of clock periods                           |         | $n_{cp1}$         |       | 20       |
| Result | Output capacitor ripple current                   | Eq. 068 | $I_{Ripple1}$     | [A]   | 0.99     |
| Result | Calculated minimum output capacitor               | Eq. 069 | $C_{Out1Cal}$     | [μF]  | 300      |
| Input  | Select output capacitor value (C11)               |         | $C_{Out1}$        | [μF]  | 470      |
| Input  | ESR ( $Z_{max}$ ) value from datasheet at 100 kHz |         | $R_{ESR1}$        | [Ω]   | 0.032    |
| Input  | Number of parallel capacitors                     |         | $n_{CCout1}$      |       | 1        |
| Result | Zero frequency of output capacitor                | Eq. 070 | $f_{ZCout1}$      | [Khz] | 10.58    |
| Result | First-stage ripple voltage                        | Eq. 071 | $V_{Ripple1}$     | [V]   | 0.085530 |
| Input  | Select LC filter inductor value (L2)              |         | $L_{out1}$        | [μH]  | 2.2      |
| Result | Calculated LC filter capacitor                    | Eq. 072 | $C_{LCCal1}$      | [μF]  | 102.8    |
| Input  | Select LC filter capacitor value (C12)            |         | $C_{LC1}$         | [μF]  | 220      |
| Result | LC filter frequency                               | Eq. 073 | $f_{LC1}$         | [Khz] | 7.23     |
| Result | Second-stage ripple voltage                       | Eq. 074 | $V_{2ndRipple1}$  | [mV]  | 0.45     |

## Secondary 2 output rectifier

|        |   |         |                   |       |       |
|--------|---|---------|-------------------|-------|-------|
| Result | Diode reverse voltage                             | Eq. 075 | $V_{RDiode2}$     | [V]   | 28.42 |
| Result | Diode RMS current                                 |         | $I_{S2RMS}$       | [A]   | 1.21  |
| Input  | Max. voltage undershoot at output capacitor       |         | $\Delta V_{Out1}$ | [V]   | 0.3   |
| Input  | Number of clock periods                           |         | $n_{cp2}$         |       | 20    |
| Result | Output capacitor ripple current                   | Eq. 076 | $I_{Ripple2}$     | [A]   | 1.10  |
| Result | Calculated minimum output capacitor               | Eq. 077 | $C_{Out2Cal}$     | [μF]  | 333   |
| Input  | Select output capacitor value (C13)               |         | $C_{Out2}$        | [μF]  | 330   |
| Input  | ESR ( $Z_{max}$ ) value from datasheet at 100 kHz |         | $R_{ESR2}$        | [Ω]   | 0.032 |
| Input  | Number of parallel capacitors                     |         | $n_{CCout2}$      |       | 1     |
| Result | Zero frequency of output capacitor                | Eq. 078 | $f_{ZCout2}$      | [Khz] | 15.07 |
| Result | First-stage ripple voltage                        | Eq. 079 | $V_{Ripple2}$     | [V]   | 0.10  |
| Input  | Select LC filter inductor value (L3)              |         | $L_{out}$         | [μH]  | 2.2   |
| Result | Calculated LC filter capacitor                    | Eq. 080 | $C_{LCCal2}$      | [μF]  | 50.7  |
| Input  | Select LC filter capacitor value (C14)            |         | $C_{LC2}$         | [μF]  | 330   |
| Result | LC filter frequency                               | Eq. 081 | $f_{LC2}$         | [Khz] | 5.91  |
| Result | Second-stage ripple voltage                       | Eq. 082 | $V_{2ndRipple2}$  | [mV]  | 0.33  |

## Appendix A: Transformer design and spreadsheet [3]

V<sub>CC</sub> diode and capacitor

|        |  |         |                          |      |         |
|--------|--|---------|--------------------------|------|---------|
| Result | Auxiliary diode reverse voltage (D1)           | Eq. 083 | V <sub>RDiodeVCC</sub>   | [V]  | 79.68   |
| Input  | Soft-start time from datasheet                 |         | t <sub>ss</sub>          | [ms] | 12      |
| Input  | I <sub>VCC_Charge3</sub> from datasheet        |         | I <sub>VCC_Charge3</sub> | [mA] | 3       |
| Input  | V <sub>CC</sub> on-threshold                   |         | V <sub>VCC_ON</sub>      | [V]  | 16      |
| Input  | V <sub>CC</sub> off-threshold                  |         | V <sub>VCC_OFF</sub>     | [V]  | 10      |
| Result | Calculated V <sub>CC</sub> capacitor           | Eq. 084 | C <sub>VCCcal</sub>      | [μF] | 6.00    |
| Input  | Select V <sub>CC</sub> capacitor (C3)          |         | C <sub>VCC</sub>         | [μF] | 22      |
| Input  | V <sub>CC</sub> short threshold from datasheet |         | V <sub>VCC_SCP</sub>     | [V]  | 1.1     |
| Input  | I <sub>VCC_Charge1</sub> from datasheet        |         | I <sub>VCC_Charge1</sub> | [mA] | 0.2     |
| Result | Start-up time                                  | Eq. 085 | t <sub>StartUp</sub>     | [ms] | 230.267 |

## Calculation of losses

## Input diode bridge

|        |                              |         |                  |     |      |
|--------|------------------------------|---------|------------------|-----|------|
| Input  | Diode bridge forward voltage |         | V <sub>FBR</sub> | [V] | 1    |
| Result | Diode bridge power loss      | Eq. 086 | P <sub>DIN</sub> | [W] | 0.48 |

## Transformer copper

|        |                                       |         |                   |      |         |
|--------|---------------------------------------|---------|-------------------|------|---------|
| Result | Primary winding copper resistance     | Eq. 087 | R <sub>PCu</sub>  | [mΩ] | 1808.16 |
| Result | Secondary 1 winding copper resistance | Eq. 088 | R <sub>S1Cu</sub> | [mΩ] | 67.85   |
| Result | Secondary 2 winding copper resistance | Eq. 089 | R <sub>S2Cu</sub> | [mΩ] | 14.13   |
| Result | Primary winding copper loss           | Eq. 090 | P <sub>PCu</sub>  | [mW] | 104.37  |
| Result | Secondary 1 winding copper loss       | Eq. 091 | P <sub>S1Cu</sub> | [mW] | 80.24   |
| Result | Secondary 2 winding copper loss       | Eq. 092 | P <sub>S2Cu</sub> | [mW] | 20.64   |
| Result | Total transformer copper loss         | Eq. 093 | P <sub>Cu</sub>   | [W]  | 0.2052  |

## Output rectifier diode

|        |                        |         |                     |     |      |
|--------|------------------------|---------|---------------------|-----|------|
| Result | Secondary 1 diode loss | Eq. 094 | P <sub>Diode1</sub> | [W] | 0.65 |
| Result | Secondary 2 diode loss | Eq. 095 | P <sub>Diode2</sub> | [W] | 0.24 |

## RCD clamper circuit

|        |                  |         |                      |     |      |
|--------|------------------|---------|----------------------|-----|------|
| Result | RCD clamper loss | Eq. 096 | P <sub>Clamper</sub> | [W] | 0.41 |
|--------|------------------|---------|----------------------|-----|------|

## CS resistor

|        |                  |         |                 |     |      |
|--------|------------------|---------|-----------------|-----|------|
| Result | CS resistor loss | Eq. 097 | P <sub>CS</sub> | [W] | 0.08 |
|--------|------------------|---------|-----------------|-----|------|

## MOSFET

|        |  |         |  |      |        |
|--------|--|---------|--|------|--------|
| Input  | R <sub>DS(on)</sub> from datasheet             |         | R <sub>DS(on) at T<sub>A</sub> = 125°C</sub> | [Ω]  | 8.73   |
| Input  | C <sub>o(er)</sub> from datasheet              |         | C <sub>o(er)</sub>                           | [pF] | 3.4    |
| Input  | External drain-to-source capacitance           |         | C <sub>DS</sub>                              | [pF] | 0      |
| Result | Switch-on loss at minimum AC input voltage     | Eq. 098 | P <sub>SONMinAC</sub>                        | [W]  | 0.0047 |
| Result | Conduction loss at minimum AC input voltage    | Eq. 099 | P <sub>condMinAC</sub>                       | [W]  | 0.5039 |
| Result | Total MOSFET loss at minimum AC input voltage  | Eq. 100 | P <sub>MOSMinAC</sub>                        | [W]  | 0.5086 |
| Result | Switch-on loss at maximum AC input voltage     | Eq. 101 | P <sub>SONMaxAC</sub>                        | [W]  | 0.0358 |
| Result | Conduction loss at maximum AC input voltage    | Eq. 102 | P <sub>condMaxAC</sub>                       | [W]  | 0.1114 |
| Result | Total MOSFET loss at maximum AC input voltage  | Eq. 103 | P <sub>MOSMaxAC</sub>                        | [W]  | 0.1472 |
| Result | Total MOSFET loss (from minimum or maximum AC) |         | P <sub>MOS</sub>                             | [W]  | 0.5086 |

## Controller

|        |                                |         |                         |      |        |
|--------|--------------------------------|---------|-------------------------|------|--------|
| Input  | Controller current consumption |         | I <sub>VCC_Normal</sub> | [mA] | 0.9    |
| Result | Controller loss                | Eq. 104 | P <sub>Ctrl</sub>       | [W]  | 0.0127 |

## Efficiency after losses

|        |                            |         |                     |           |               |
|--------|----------------------------|---------|---------------------|-----------|---------------|
| Result | Total power loss           | Eq. 105 | P <sub>Losses</sub> | [W]       | 2.59          |
| Result | Post calculated efficiency | Eq. 106 | η <sub>Post</sub>   | [Percent] | 80.05 percent |

## CoolSET™/MOSFET temperature

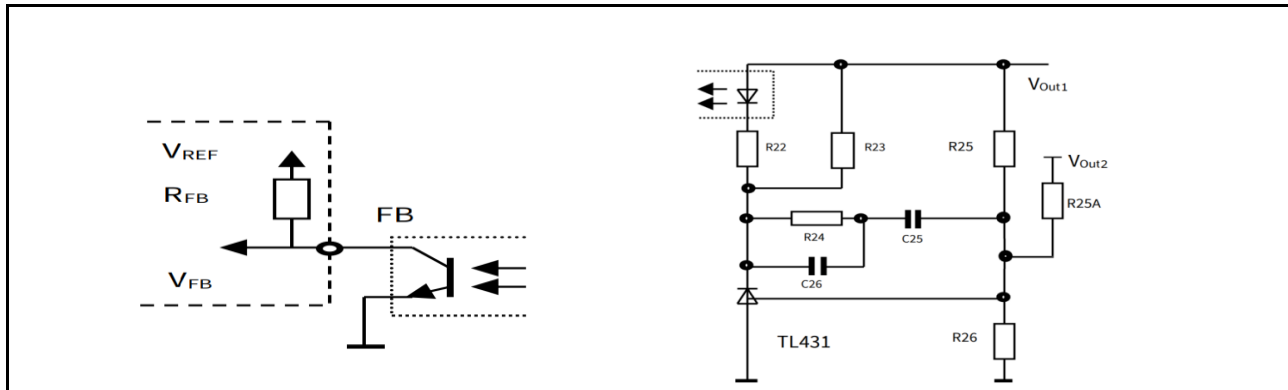
## CoolSET™/MOSFET temperature

|        |   |         |                      |        |      |
|--------|---|---------|----------------------|--------|------|
| Input  | Thermal resistance junction-ambient (include copper pour) |         | R <sub>thJA,As</sub> | [°K/W] | 65.0 |
| Result | Temperature rise  | Eq. 107 | ΔT                   | [°K]   | 33.1 |
| Result | Junction temperature at T <sub>amax</sub>                 | Eq. 108 | T <sub>jmax</sub>    | °C     | 83.1 |

## Appendix A: Transformer design and spreadsheet [3]

Output regulation (isolated using TL431 and optocoupler)

Isolated FB circuit



## Output regulation

|        |  |         |                |      |          |
|--------|--|---------|----------------|------|----------|
| Input  | TL431 reference voltage                  |         | $V_{REF\_TL}$  | [V]  | 2.5      |
| Input  | Weighted regulation factor of $V_{Out1}$ |         | $W_1$          |      | 0        |
| Input  | Current for voltage divider resistor R26 |         | $I_{R26}$      | [mA] | 0.208    |
| Result | Calculated voltage divider resistor      | Eq. 111 | $R_{26\_Cal}$  | [kΩ] | 12       |
| Input  | Select voltage divider resistor value    |         | $R_{26}$       | [kΩ] | 12       |
| Result | Calculated voltage divider resistor      | Eq. 112 | $R_{25\_Cal}$  | [kΩ] | #DIV/0!  |
| Input  | Select voltage divider resistor value    |         | $R_{25}$       | [kΩ] | 1.00E+30 |
| Result | Calculated voltage divider resistor      | Eq. 113 | $R_{25A\_Cal}$ | [kΩ] | 12.00    |
| Input  | Select voltage divider resistor value    |         | $R_{25A}$      | [kΩ] | 12       |

## Optocoupler and TL431 bias

|        |   |         |               |           |             |
|--------|---|---------|---------------|-----------|-------------|
| Input  | Current Transfer Ratio (CTR)                          |         | $G_c$         | [Percent] | 200 percent |
| Input  | Optocoupler diode forward voltage                     |         | $V_{FOpto}$   | [V]       | 1.25        |
| Input  | Maximum current for optocoupler diode                 |         | $I_{Fmax}$    | [mA]      | 50          |
| Input  | Minimum current for TL431                             |         | $I_{KAmin}$   | [mA]      | 1           |
| Result | Calculated minimum optocoupler bias resistance (R7)   | Eq. 114 | $R_{22\_Cal}$ | [kΩ]      | 0.0250      |
| Input  | Select optocoupler bias resistor (R7)                 |         | $R_{22}$      | [kΩ]      | 0.33        |
| Input  | FB pull-up reference voltage $V_{REF}$ from datasheet |         | $V_{REF}$     | [V]       | 3.3         |
| Input  | $V_{FB\_OLP}$ from datasheet                          |         | $V_{FB\_OLP}$ | [V]       | 2.75        |
| Input  | $R_{FB}$ from datasheet                               |         | $R_{FB}$      | [kΩ]      | 15          |
| Result | Calculated maximum TL431 bias resistance (R8)         | Eq. 115 | $R_{23\_Cal}$ | [kΩ]      | 1.26        |
| Input  | Selected TL431 bias resistor (R8)                     |         | $R_{23}$      | [kΩ]      | 1.2         |

## Regulation loop

|        |   |         |                  |       |          |
|--------|---|---------|------------------|-------|----------|
| Result | FB transfer characteristic                                | Eq. 116 | $K_{FB}$         |       | 90.91    |
| Result | Gain of FB transfer characteristic                        | Eq. 117 | $G_{FB}$         | [dB]  | 39.17    |
| Result | Voltage divider transfer characteristic                   | Eq. 118 | $K_{VD}$         |       | 0.208333 |
| Result | Gain of voltage divider transfer characteristic           | Eq. 119 | $G_{VD}$         | [dB]  | -13.62   |
| Result | Resistance at maximum load pole                           | Eq. 120 | $R_{LH}$         | [Ω]   | 13.85    |
| Result | Resistance at minimum load pole                           | Eq. 121 | $R_{LL}$         | [Ω]   | 72.00    |
| Result | Poles of power stage at maximum load pole                 | Eq. 122 | $f_{OH}$         | [Hz]  | 48.91    |
| Result | Poles of power stage at minimum load pole                 | Eq. 123 | $f_{OL}$         | [Hz]  | 9.41     |
| Result | Zero frequency of the compensation network                | Eq. 124 | $f_{OM}$         | [Hz]  | 21.45    |
| Input  | Zero dB crossover frequency                               |         | $f_g$            | [kHz] | 8        |
| Input  | PWM-OP gain from datasheet                                |         | $A_V$            |       | 2.03     |
| Result | Transient impedance                                       | Eq. 117 | $Z_{PWM}$        | [V/A] | 3.5      |
| Result | Power stage at crossover frequency                        | Eq. 118 | $ F_{PWR}(f_g) $ |       | 0.036    |
| Result | Gain of power stage at crossover frequency                | Eq. 119 | $G_{PWR}(f_g)$   | [dB]  | -28.84   |
| Result | Gain of the regulation loop at $f_g$                      | Eq. 120 | $G_S(\omega)$    | [dB]  | -3.292   |
| Result | Separated components of the regulator                     | Eq. 121 | $G_R(\omega)$    | [dB]  | 3.292    |
| Result | Calculated resistance value of compensation network (R9)  | Eq. 122 | $R_{24\_Cal}$    | [kΩ]  | 17.53    |
| Input  | Select resistor value of compensation network (R9)        |         | $R_{24}$         | [kΩ]  | 18       |
| Result | Calculated capacitance value of compensation network (C7) | Eq. 123 | $C_{26\_Cal}$    | [nF]  | 1.105    |

## Appendix A: Transformer design and spreadsheet [3]

|        |   |         |                    |      |        |
|--------|---|---------|--------------------|------|--------|
| Input  | Select capacitor value of compensation network (C7)       |         | C26                | [nF] | 1      |
| Result | Calculated capacitance value of compensation network (C8) | Eq. 124 | C25 <sub>cal</sub> | [nF] | 411.22 |
| Input  | Select capacitor value of compensation network (C8)       |         | C25                | [nF] | 220    |

## Final design

## Electrical

|                          |  |  |           |               |
|--------------------------|--|--|-----------|---------------|
| Minimum AC voltage       |  |  | [V]       | 85            |
| Maximum AC voltage       |  |  | [V]       | 265           |
| Maximum input current    |  |  | [A]       | 0.14          |
| Minimum DC voltage       |  |  | [V]       | 83            |
| Maximum DC voltage       |  |  | [V]       | 375           |
| Maximum output power     |  |  | [W]       | 10.4          |
| Output voltage 1         |  |  | [V]       | 12.0          |
| Output ripple voltage 1  |  |  | [mV]      | 0.4           |
| Output voltage 2         |  |  | [V]       | 5.0           |
| Output ripple voltage 2  |  |  | [mV]      | 0.3           |
| Transformer peak current |  |  | [A]       | 0.59          |
| Maximum duty cycle       |  |  |           | 0.50          |
| Reflected voltage        |  |  | [V]       | 84            |
| Copper losses            |  |  | [W]       | 0.21          |
| MOSFET losses            |  |  | [W]       | 0.51          |
| Sum losses               |  |  | [W]       | 2.59          |
| Efficiency               |  |  | [Percent] | 80.05 percent |

## Transformer

|  |  |  |                    |            |
|--|--|--|--------------------|------------|
| Core type                                      |  |  |                    | EE16/8/5   |
| Core material                                  |  |  |                    | TP4A (TDG) |
| Effective core area                            |  |  | [mm <sup>2</sup> ] | 20.1       |
| Maximum flux density                           |  |  | [mT]               | 259        |
| Inductance                                     |  |  | [μH]               | 711        |
| Margin   |  |  | [mm]               | 0          |
| Primary turns                                  |  |  | Turns              | 80         |
| Primary copper wire size                       |  |  | AWG                | 33         |
| Number of primary copper wires in parallel     |  |  |                    | 1          |
| Primary layers                                 |  |  | Layer              | 3          |
| Secondary 1 turns (N <sub>s1</sub> )           |  |  | Turns              | 12         |
| Secondary 1 copper wire size                   |  |  | AWG                | 27         |
| Number of secondary 1 copper wires in parallel |  |  |                    | 1          |
| Secondary 1 layers                             |  |  | Layer              | 1          |
| Secondary 2 turns (N <sub>s2</sub> )           |  |  | Turns              | 5          |
| Secondary 2 copper wire size                   |  |  | AWG                | 27         |
| Number of secondary 2 copper wires in parallel |  |  |                    | 2          |
| Secondary 2 layers                             |  |  | Layer              | 1          |
| Auxiliary turns                                |  |  | Turns              | 14         |
| Leakage inductance                             |  |  | [μH]               | 17.8       |

## Components

|  |  |  |      |       |
|--|--|--|------|-------|
| Input capacitor (C1)                     |  |  | [μF] | 20.0  |
| Secondary 1 output capacitor (C152)      |  |  | [μF] | 470.0 |
| Secondary 1 output capacitor in parallel |  |  |      | 1.0   |
| Secondary 1 LC filter inductor (L151)    |  |  | [μH] | 2.2   |
| Secondary 1 LC filter capacitor (C153)   |  |  | [μF] | 220.0 |
| Secondary 2 output capacitor (C102)      |  |  | [μF] | 330.0 |
| Secondary 2 output capacitor in parallel |  |  |      | 1.0   |
| Secondary 2 LC filter inductor (L101)    |  |  | [μH] | 2.2   |
| Secondary 2 LC filter capacitor (C103)   |  |  | [μF] | 330.0 |
| V <sub>CC</sub> capacitor (C3)           |  |  | [μF] | 22.0  |
| Sense resistor (R8A, R8B)                |  |  | [Ω]  | 1.36  |
| Clamping resistor (R4)                   |  |  | [kΩ] | 240.0 |
| Clamping capacitor (C2)                  |  |  | [nF] | 0     |



## Appendix A: Transformer design and spreadsheet [3]

## Regulation components (isolated using TL431 and optocoupler)

|                                     |  |      |      |       |
|-------------------------------------|--|------|------|-------|
| Voltage divider                     |  | R26  | [kΩ] | 12.0  |
| Voltage divider ( $V_{out1}$ sense) |  | R25  | [kΩ] |       |
| Voltage divider ( $V_{out2}$ sense) |  | R25A | [kΩ] | 12.0  |
| Optocoupler bias resistor           |  | R22  | [kΩ] | 0.33  |
| TL431 bias resistor                 |  | R23  | [kΩ] | 1.2   |
| Compensation network resistor       |  | R24  | [kΩ] | 18.0  |
| Compensation network capacitor      |  | C26  | [nF] | 1.00  |
| Compensation network capacitor      |  | C25  | [nF] | 220.0 |

# 8 W auxiliary SMPS for air-conditioner using ICE5AR4770BZS

REF\_5AR4770BZS\_8W1

## Appendix B: WE transformer specification

### 12 Appendix B: WE transformer specification

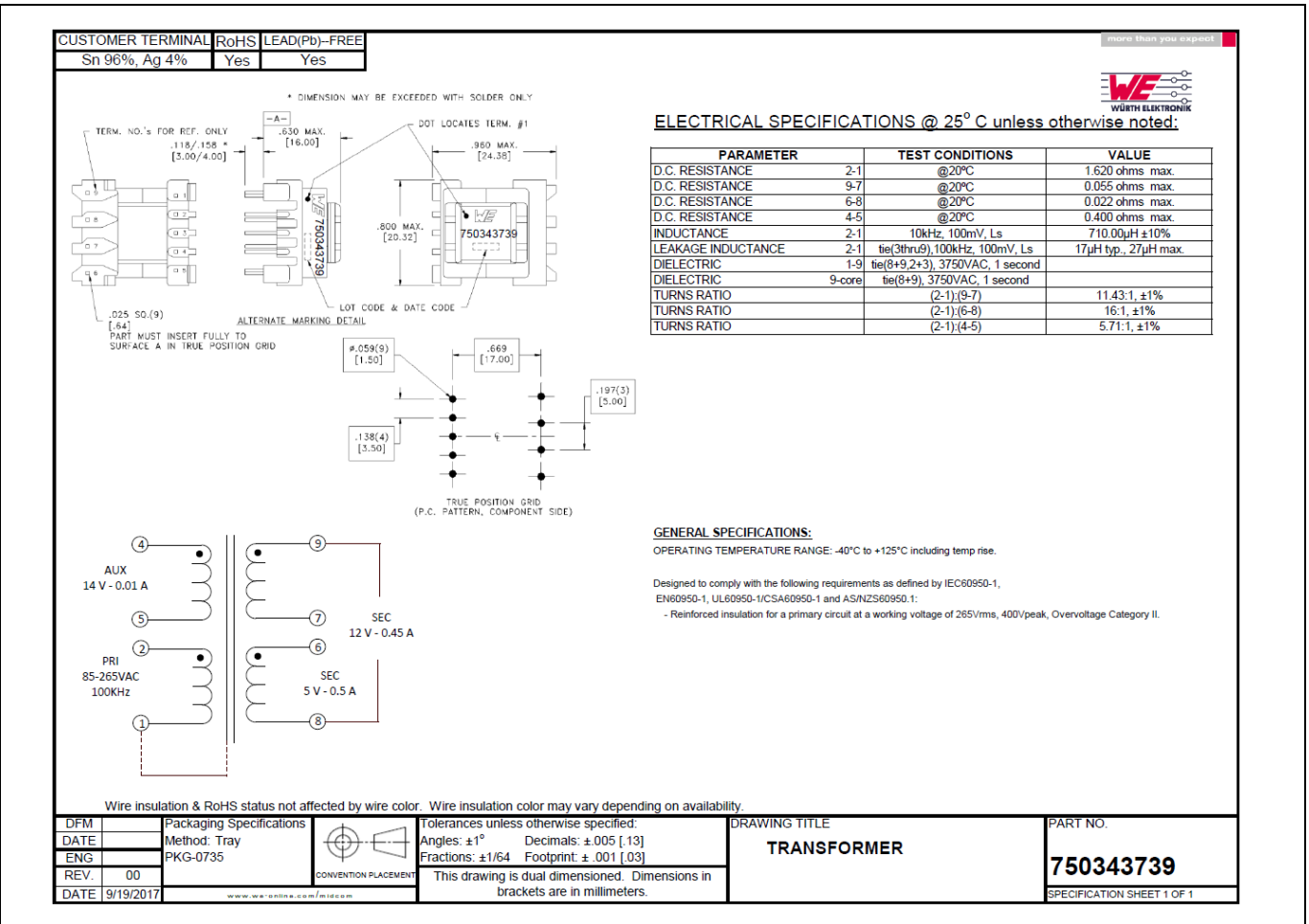


Figure 34 Transformer structure

### References

## 13 References

- [1] ICE5AR4770BZS datasheet, Infineon Technologies AG
- [2] 5<sup>th</sup>-Generation Fixed-Frequency Design Guide
- [3] Calculation Tool Fixed-Frequency CoolSET™ Generation 5

Revision history

Revision history

| Document version | Date of release | Description of changes |
|------------------|-----------------|------------------------|
| V 1.0            | 6 Feb 2018      | First release          |
|                  |                 |                        |
|                  |                 |                        |

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**Do you have a question about this document?**

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**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331